

2-GHz, LOW DISTORTION, CURRENT FEEDBACK AMPLIFIERS

FEATURES

- **Unity Gain Bandwidth: 2 GHz**
- **High Slew Rate: 9000 V/ μ s**
- **IMD3 at 120 MHz: -89 dBc ($G = 5$, $R_L = 100 \Omega$, $V_{CC} = 15 V$)**
- **OIP3 at 120 MHz: 44 dBm ($G = 5$, $R_L = 100 \Omega$, $V_{CC} = 15 V$)**
- **High Output Current: ± 115 mA into $20 \Omega R_L$**
- **Power Supply Voltage Range: 6.6 V to 15 V**

APPLICATIONS

- **High-Speed Signal Processing**
- **Test and Measurement Systems**
- **High-Voltage ADC Pre-amplifier**
- **RF and IF Amplifier Stages**
- **Professional Video**

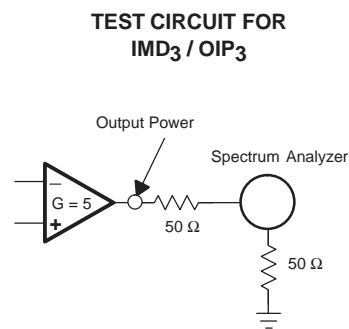
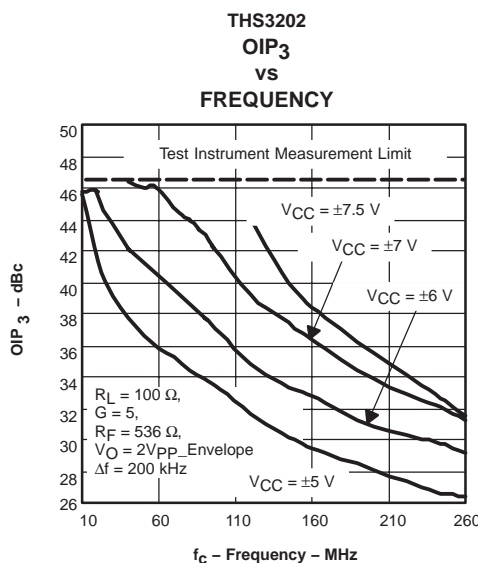
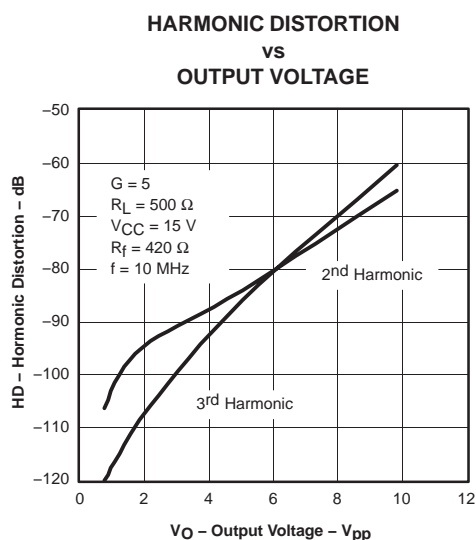
DESCRIPTION

The THS3202 is part of the high performing current feedback amplifier family developed in BiCOM-II technology. Designed for low-distortion with a high slew rate of 9000 V/ μ s, the THS320x family is ideally suited for applications driving loads sensitive to distortion at high frequencies.

The THS3202 provides well-regulated ac performance characteristics with power supplies ranging from single-supply 6.6-V operation up to a 15-V supply. The high unity gain bandwidth of up to 2 GHz is a major contributor to the excellent distortion performance. The THS3202 offers an output current drive of ± 115 mA and a low differential gain and phase error that make it suitable for applications such as video line drivers.

The THS3202 is available in an 8 pin SOIC and an 8 pin MSOP with PowerPAD™ packages.

RELATED DEVICES AND DESCRIPTIONS	
THS3001	± 15 -V 420-MHz Low Distortion CFB Amplifier
THS3061/2	± 15 -V 300-MHz Low Distortion CFB Amplifier
THS3122	± 15 -V Dual CFB Amplifier With 350 mA Drive
THS4271	+15-V 1.4-GHz Low Distortion VFB Amplifier



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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THS3202

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ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range unless otherwise noted⁽¹⁾

	UNIT	
Supply voltage, V_S	16.5 V	
Input voltage, V_I	$\pm V_S$	
Differential Input voltage, V_{ID}	± 3 V	
Output current, I_O ⁽²⁾	175 mA	
Continuous power dissipation	See Dissipation Rating Table	
Maximum junction temperature, T_J ⁽³⁾	150°C	
Maximum junction temperature, continuous operation, long term reliability T_J ⁽⁴⁾	125°C	
Operating free-air temperature range, T_A	-40°C to 85°C	
Storage temperature range, T_{stg}	-65°C to 150°C	
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	300°C	
ESD ratings:	HBM	3000 V
	CDM	1500 V
	MM	200 V

- Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
- The THS3202 may incorporate a PowerPAD™ on the underside of the chip. This acts as a heat sink and must be connected to a thermally dissipative plane for proper power dissipation. Failure to do so may result in exceeding the maximum junction temperature which could permanently damage the device. See TI technical briefs SLMA002 and SLMA004 for more information about utilizing the PowerPAD thermally enhanced package.
- The absolute maximum temperature under any condition is limited by the constraints of the silicon process.
- The maximum junction temperature for continuous operation is limited by package constraints. Operation above this temperature may result in reduced reliability and/or lifetime of the device.

PACKAGE/ORDERING INFORMATION

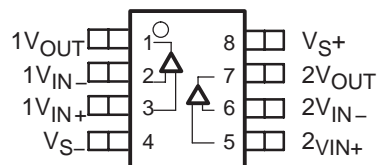
NUMBER OF CHANNELS	ORDERABLE PACKAGE AND NUMBER				
	PLASTIC SOIC-8 ⁽¹⁾ (D)	PLASTIC MSOP-8 ⁽¹⁾ PowerPAD		PLASTIC MSOP-8 ⁽¹⁾	
		(DGN)	SYM	(DGK)	SYM
2	THS3202D	THS3202DGN	BEP	THS3202DGK	BEV

⁽¹⁾ This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., THS3202DR).

PIN ASSIGNMENTS

TOP VIEW

D, DGN, DGK



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGE DISSIPATION RATINGS

PACKAGE	θ_{JC} (°C/W)	θ_{JA} ⁽¹⁾ (°C/W)	POWER RATING ⁽²⁾	
			$T_A \leq 25^\circ\text{C}$	$T_A = 85^\circ\text{C}$
D (8 pin)	38.3	97.5	1.32 W	410 mW
DGN (8 pin)	4.7	58.4	1.71 W	685 mW
DGK (8 pin)	54.2	260	385 mW	154 mW

- This data was taken using the JEDEC standard High-K test PCB.
- Power rating is determined with a junction temperature of 125°C. This is the point where distortion starts to substantially increase. Thermal management of the final PCB should strive to keep the junction temperature at or below 125°C for best performance and long term reliability.

RECOMMENDED OPERATING CONDITIONS

	MIN	MAX	UNIT	
Supply voltage, (V_{S+} and V_{S-})	Dual supply	± 3.3	± 7.5	V
	Single supply	6.6	15	
Operating free-air temperature range	-40	85	°C	

ELECTRICAL CHARACTERISTICS
 $V_S = \pm 5\text{ V}$; $R_f = 500\ \Omega$, $R_L = 100\ \Omega$, and $G = +2$ unless otherwise noted

PARAMETER	TEST CONDITIONS	THS3202						
		TYP	OVER TEMPERATURE				UNITS	MIN/TYP/ MAX
		25°C	25°C	0°C to 70°C	-40°C to 85°C			
AC PERFORMANCE								
Small-signal bandwidth, -3 dB ($V_O = 100\text{ mV}_{pp}$)	$G = +1$, $R_f = 500\ \Omega$	1800				MHz	Typ	
	$G = +2$, $R_f = 402\ \Omega$	975						
	$G = +5$, $R_f = 300\ \Omega$	780						
	$G = +10$, $R_f = 200\ \Omega$	550						
Bandwidth for 0.1 dB flatness	$G = +2$, $V_O = 100\text{ mV}_{pp}$, $R_f = 536\ \Omega$	380				MHz	Typ	
Large-signal bandwidth	$G = +2$, $V_O = 4\text{ V}_{pp}$, $R_f = 536\ \Omega$	875				MHz	Typ	
Slew rate (25% to 75% level)	$G = -1$, 5-V step	5100				V/ μs	Typ	
	$G = +2$, 5-V step	4400						
Rise and fall time	$G = +2$, $V_O = 5\text{-V step}$	0.45				ns	Typ	
Settling time to 0.1% 0.01%	$G = -2$, $V_O = 2\text{-V step}$	19				ns	Typ	
	$G = -2$, $V_O = 2\text{-V step}$	118						
Harmonic distortion	$G = +2$, $f = 16\text{ MHz}$, $V_O = 2\text{ V}_{pp}$							
2 nd harmonic	$R_L = 100\ \Omega$	-64				dBc	Typ	
	$R_L = 500\ \Omega$	-67						
3 rd harmonic	$R_L = 100\ \Omega$	-67				dBc	Typ	
	$R_L = 500\ \Omega$	-69						
3 rd order intermodulation distortion	$G = +5$, $f_c = 120\text{ MHz}$, $\Delta f = 200\text{ kHz}$, $V_O(\text{envelope}) = 2\text{ V}_{pp}$	-64				dBc	Typ	
Input voltage noise	$f > 10\text{ MHz}$	1.65				nV/ $\sqrt{\text{Hz}}$	Typ	
Input current noise (noninverting)	$f > 10\text{ MHz}$	13.4				pA/ $\sqrt{\text{Hz}}$	Typ	
Input current noise (inverting)	$f > 10\text{ MHz}$	20				pA/ $\sqrt{\text{Hz}}$	Typ	
Crosstalk	$G = +2$, $f = 100\text{ MHz}$	-60				dB	Typ	
Differential gain (NTSC, PAL)	$G = +2$, $R_L = 150\ \Omega$	0.008%					Typ	
Differential phase (NTSC, PAL)	$G = +2$, $R_L = 150\ \Omega$	0.03°					Typ	
DC PERFORMANCE								
Open-loop transimpedance gain	$V_O = \pm 1\text{ V}$, $R_L = 1\text{ k}\Omega$	300	200	140	120	k Ω	Min	
Input offset voltage	$V_{CM} = 0\text{ V}$	± 0.7	± 3	± 3.8	± 4	mV	Max	
Average offset voltage drift	$V_{CM} = 0\text{ V}$			± 10	± 13	$\mu\text{V}/^\circ\text{C}$	Typ	
Input bias current (inverting)	$V_{CM} = 0\text{ V}$	± 13	± 60	± 80	± 85	μA	Max	
Average bias current drift (-)	$V_{CM} = 0\text{ V}$			± 300	± 400	nA/ $^\circ\text{C}$	Typ	
Input bias current (noninverting)	$V_{CM} = 0\text{ V}$	± 14	± 35	± 45	± 50	μA	Max	
Average bias current drift (+)	$V_{CM} = 0\text{ V}$			± 300	± 400	nA/ $^\circ\text{C}$	Typ	

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ELECTRICAL CHARACTERISTICS

 $V_S = \pm 5\text{ V}$; $R_f = 500\ \Omega$, $R_L = 100\ \Omega$, and $G = +2$ unless otherwise noted

PARAMETER	TEST CONDITIONS	THS3202						
		TYP	OVER TEMPERATURE				UNITS	MIN/TYP/ MAX
		25°C	25°C	0°C to 70°C	-40°C to 85°C			
INPUT								
Common-mode input range		± 2.6	± 2.5	± 2.5	± 2.5	V	Min	
Common-mode rejection ratio	$V_{CM} = \pm 2.5\text{ V}$	71	60	58	58	dB	Min	
Input resistance	Noninverting	780				k Ω	Typ	
	Inverting	11				Ω	Typ	
Input capacitance	Noninverting	1				pF	Typ	
OUTPUT								
Voltage output swing	$R_L = 1\text{ k}\Omega$	± 3.65	± 3.5	± 3.45	± 3.4	V	Min	
	$R_L = 100\ \Omega$	± 3.45	± 3.3	± 3.25	± 3.2			
Current output, sourcing	$R_L = 20\ \Omega$	115	105	100	100	mA	Min	
Current output, sinking	$R_L = 20\ \Omega$	100	85	80	80	mA	Min	
Closed-loop output impedance	$G = +1$, $f = 1\text{ MHz}$	0.01				Ω	Typ	
POWER SUPPLY								
Minimum operating voltage	Absolute minimum		± 3	± 3	± 3	V	Min	
Maximum quiescent current	Per amplifier	14	16.8	19	20	mA	Max	
Power supply rejection (+PSRR)	$V_{S+} = 4.5\text{ V to } 5.5\text{ V}$	69	63	60	60	dB	Min	
Power supply rejection (-PSRR)	$V_{S-} = -4.5\text{ V to } -5.5\text{ V}$	65	58	55	55	dB	Min	

ELECTRICAL CHARACTERISTICS
 $V_S = 15\text{ V}$; $R_f = 500\ \Omega$, $R_L = 100\ \Omega$, and $G = +2$ unless otherwise noted

PARAMETER	TEST CONDITIONS	THS3202						
		TYP	OVER TEMPERATURE				UNITS	MIN/TYP/ MAX
		25°C	25°C	0°C to 70°C	-40°C to 85°C			
AC PERFORMANCE								
Small-signal bandwidth, -3dB ($V_O = 100\text{ mV}_{pp}$)	$G = +1$, $R_f = 550\ \Omega$	2000				MHz	Typ	
	$G = +2$, $R_f = 550\ \Omega$	1100						
	$G = +5$, $R_f = 300\ \Omega$	850						
	$G = +10$, $R_f = 200\ \Omega$	750						
Bandwidth for 0.1 dB flatness	$G = +2$, $V_O = 100\text{ mV}_{pp}$, $R_f = 536\ \Omega$	500				MHz	Typ	
Large-signal bandwidth	$G = +2$, $V_O = 4\text{ V}_{pp}$, $R_f = 536\ \Omega$	1000				MHz	Typ	
Slew rate (25% to 75% level)	$G = +5$, 5-V step	7500				V/ μ s	Typ	
	$G = +2$, 10-V step	9000						
Rise and fall time	$G = +2$, $V_O = 10\text{-V}$ step	0.45				ns	Typ	
Settling time to 0.1% 0.01%	$G = -2$, $V_O = 2\text{-V}$ step	23				ns	Typ	
	$G = -2$, $V_O = 2\text{-V}$ step	112				ns	Typ	
Harmonic distortion	$G = +2$, $f = 16\text{ MHz}$, $V_O = 2\text{ V}_{pp}$							
2 nd harmonic	$R_L = 100\ \Omega$	-69				dBc	Typ	
	$R_L = 500\ \Omega$	-73						
3 rd harmonic	$R_L = 100\ \Omega$	-80				dBc	Typ	
	$R_L = 500\ \text{k}\Omega$	-90						
3 rd order intermodulation distortion	$G = +5$, $f_C = 120\text{ MHz}$, $\Delta f = 200\text{ kHz}$, $V_O(\text{envelope}) = 2\text{ V}_{pp}$	-89				dBc	Typ	
Input voltage noise	$f > 10\text{ MHz}$	1.65				nV/ $\sqrt{\text{Hz}}$	Typ	
Input current noise (noninverting)	$f > 10\text{ MHz}$	13.4				pA/ $\sqrt{\text{Hz}}$	Typ	
Input current noise (inverting)	$f > 10\text{ MHz}$	20				pA/ $\sqrt{\text{Hz}}$	Typ	
Crosstalk	$G = +2$, $f = 100\text{ MHz}$	-60				dB	Typ	
Differential gain (NTSC, PAL)	$G = +2$, $R_L = 150\ \Omega$	0.004%					Typ	
Differential phase (NTSC, PAL)	$G = +2$, $R_L = 150\ \Omega$	0.006°					Typ	
DC PERFORMANCE								
Open-loop transimpedance gain	$V_O = 6.5\text{ V}$ to 8.5 V , $R_L = 1\text{ k}\Omega$	300	200	140	120	k Ω	Min	
Input offset voltage	$V_{CM} = 7.5\text{ V}$	± 1.3	± 4	± 4.8	± 5	mV	Max	
Average offset voltage drift	$V_{CM} = 7.5\text{ V}$			± 10	± 13	$\mu\text{V}/^\circ\text{C}$	Typ	
Input bias current (inverting)	$V_{CM} = 7.5\text{ V}$	± 16	± 60	± 80	± 85	μA	Max	
Average bias current drift (-)	$V_{CM} = 7.5\text{ V}$			± 300	± 400	nA/ $^\circ\text{C}$	Typ	
Input bias current (noninverting)	$V_{CM} = 7.5\text{ V}$	± 14	± 35	± 45	± 50	μA	Max	
Average bias current drift (+)	$V_{CM} = 7.5\text{ V}$			± 300	± 400	nA/ $^\circ\text{C}$	Typ	

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ELECTRICAL CHARACTERISTICS continued

 $V_S = 15\text{ V}$; $R_f = 500\ \Omega$, $R_L = 100\ \Omega$, and $G = +2$ unless otherwise noted

PARAMETER	TEST CONDITIONS	THS3202						
		TYP	OVER TEMPERATURE				UNITS	MIN/TYP/ MAX
		25°C	25°C	0°C to 70°C	-40°C to 85°C			
INPUT								
Common-mode input range		2.4 to 12.6	2.5 to 12.5	2.5 to 12.5	2.5 to 12.5	V	Min	
Common-mode rejection ratio	$V_{CM} = 5\text{ V to }10\text{ V}$	69	60	58	58	dB	Min	
Input resistance	Noninverting	780				k Ω	Typ	
	Inverting	11				Ω	Typ	
Input capacitance	Noninverting	1				pF	Typ	
OUTPUT								
Voltage output swing	$R_L = 1\text{ k}\Omega$	1.5 to 13.5	1.6 to 13.4	1.7 to 13.3	1.7 to 13.3	V	Min	
	$R_L = 100\ \Omega$	1.7 to 13.3	1.8 to 13.2	2.0 to 13.0	2.0 to 13.0			
Current output, sourcing	$R_L = 20\ \Omega$	120	105	100	100	mA	Min	
Current output, sinking	$R_L = 20\ \Omega$	115	95	90	90	mA	Min	
Closed-loop output impedance	$G = +1$, $f = 1\text{ MHz}$	0.01				Ω	Typ	
POWER SUPPLY								
Maximum quiescent current/channel	Per amplifier	15	18	21	21	mA	Max	
Power supply rejection (+PSRR)	$V_{S+} = 14.50\text{ V to }15.50\text{ V}$	69	63	60	60	dB	Min	
Power supply rejection (-PSRR)	$V_{S-} = -0.5\text{ V to }+0.5\text{ V}$	65	58	55	55	dB	Min	

TYPICAL CHARACTERISTICS

Table of Graphs

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SMALL SIGNAL FREQUENCY RESPONSE

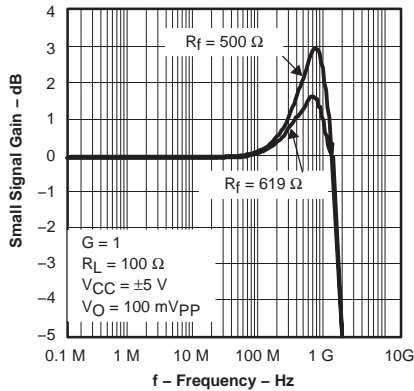


Figure 1

SMALL SIGNAL FREQUENCY RESPONSE

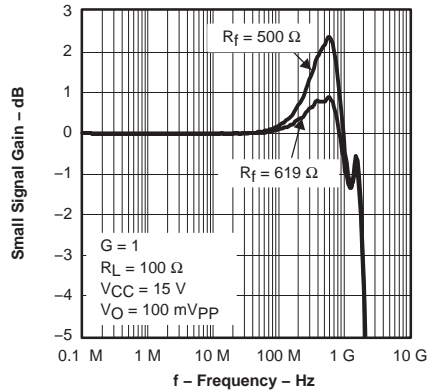


Figure 2

SMALL SIGNAL FREQUENCY RESPONSE

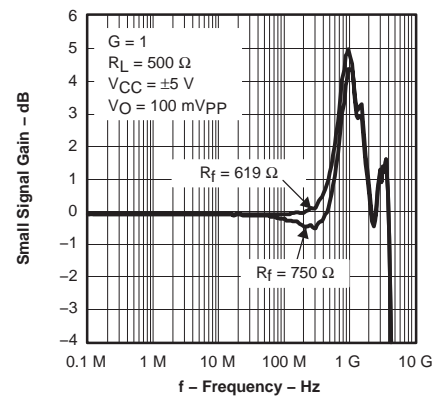


Figure 3

SMALL SIGNAL FREQUENCY RESPONSE

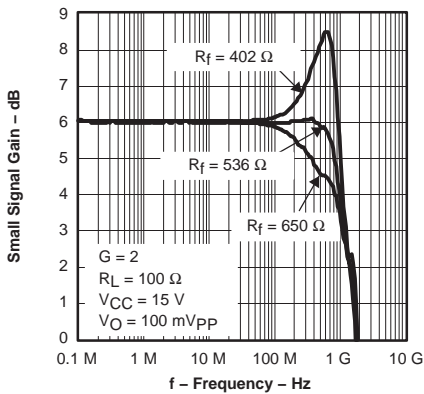


Figure 4

SMALL SIGNAL FREQUENCY RESPONSE

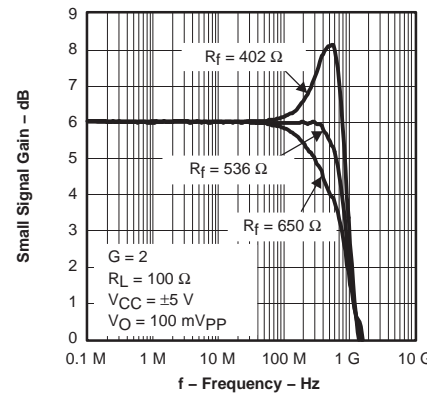


Figure 5

SMALL SIGNAL FREQUENCY RESPONSE

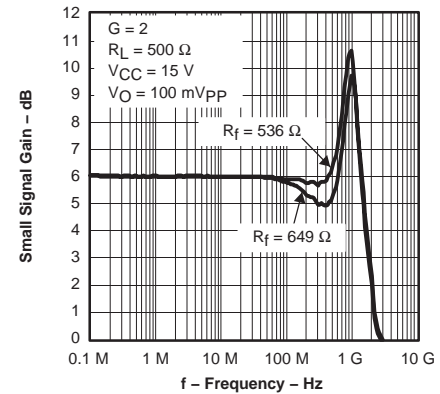


Figure 6

SMALL SIGNAL FREQUENCY RESPONSE

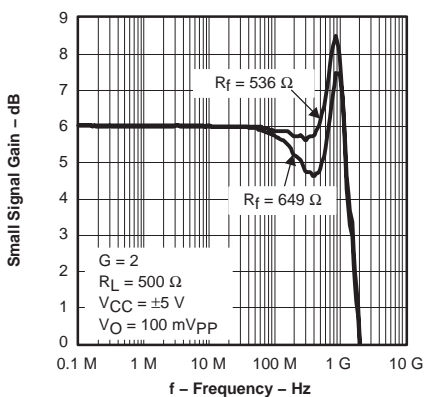


Figure 7

SMALL SIGNAL FREQUENCY RESPONSE

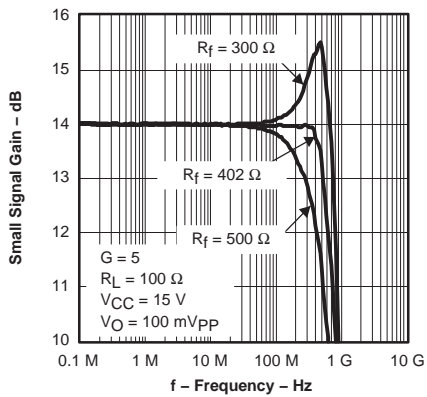


Figure 8

SMALL SIGNAL FREQUENCY RESPONSE

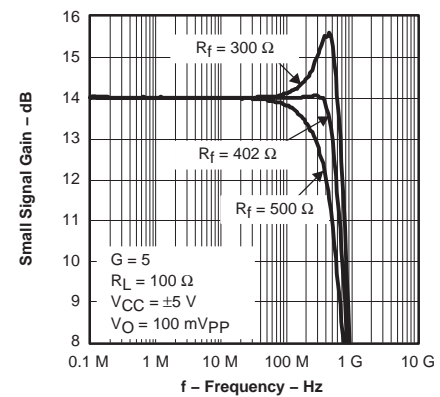


Figure 9

SMALL SIGNAL FREQUENCY RESPONSE

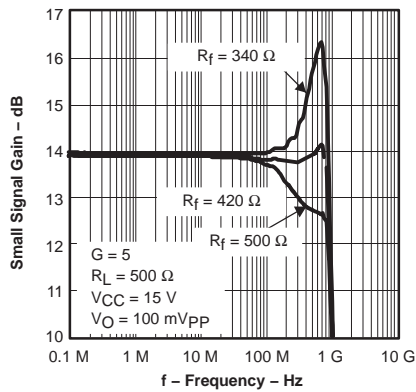


Figure 10

SMALL SIGNAL FREQUENCY RESPONSE

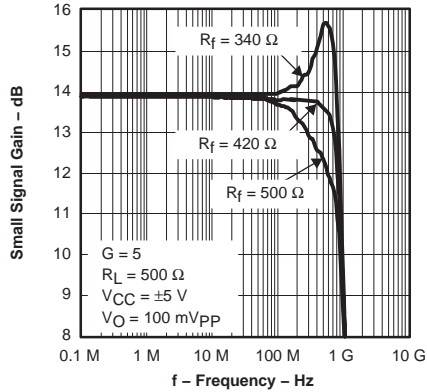


Figure 11

SMALL SIGNAL FREQUENCY RESPONSE

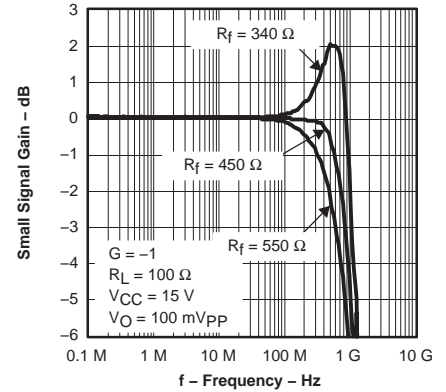


Figure 12

SMALL SIGNAL FREQUENCY RESPONSE

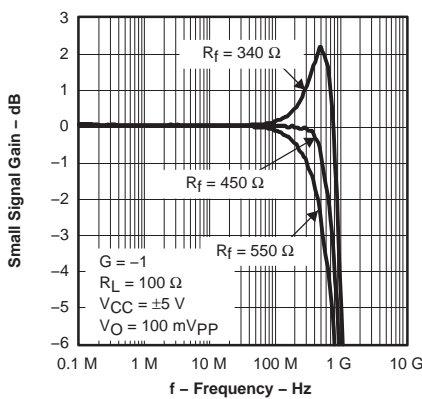


Figure 13

SMALL SIGNAL FREQUENCY RESPONSE

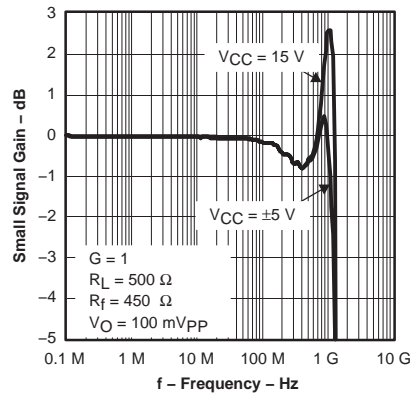


Figure 14

LARGE SIGNAL FREQUENCY RESPONSE

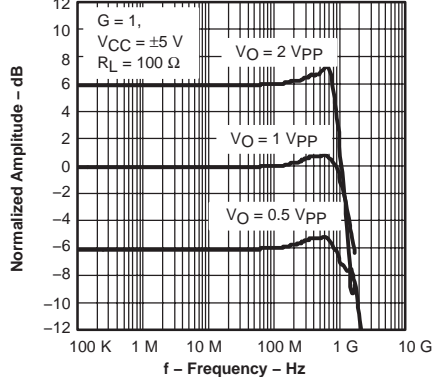


Figure 15

LARGE SIGNAL FREQUENCY RESPONSE

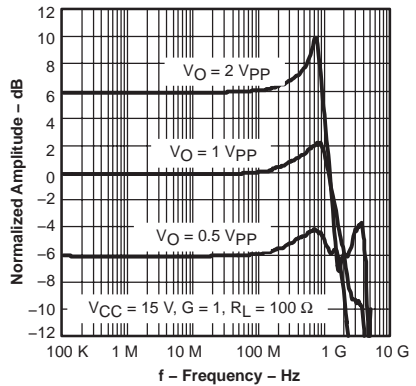


Figure 16

LARGE SIGNAL FREQUENCY RESPONSE

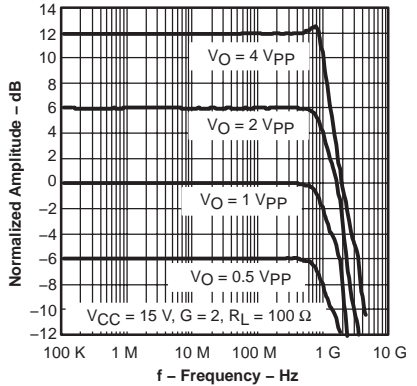


Figure 17

LARGE SIGNAL FREQUENCY RESPONSE

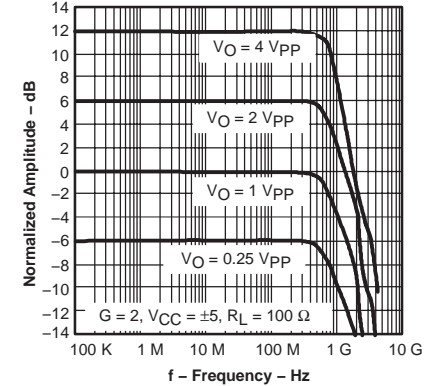


Figure 18

**HARMONIC DISTORTION
VS
FREQUENCY**

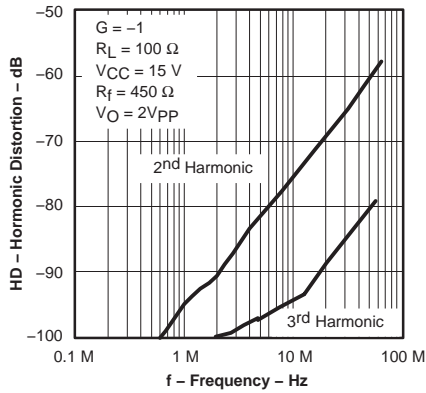


Figure 19

**HARMONIC DISTORTION
VS
FREQUENCY**

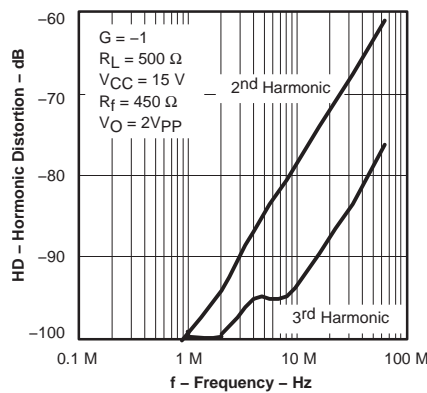


Figure 20

**HARMONIC DISTORTION
VS
FREQUENCY**

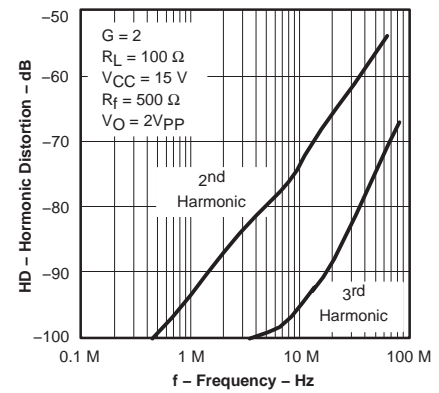


Figure 21

**HARMONIC DISTORTION
VS
FREQUENCY**

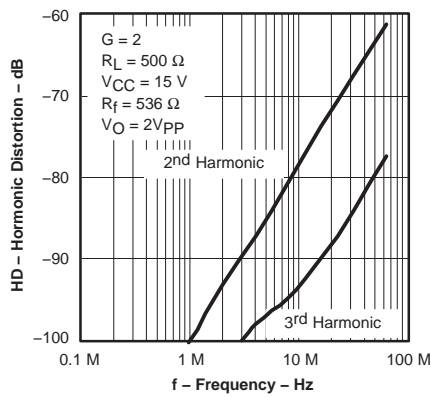


Figure 22

**HARMONIC DISTORTION
VS
FREQUENCY**

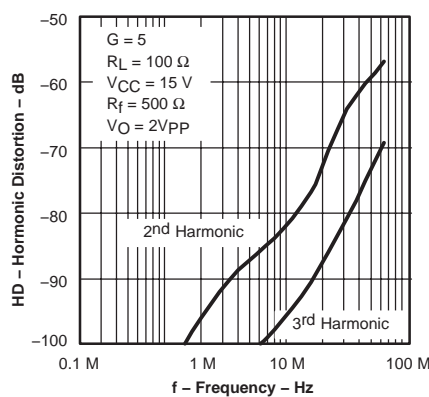


Figure 23

**HARMONIC DISTORTION
VS
FREQUENCY**

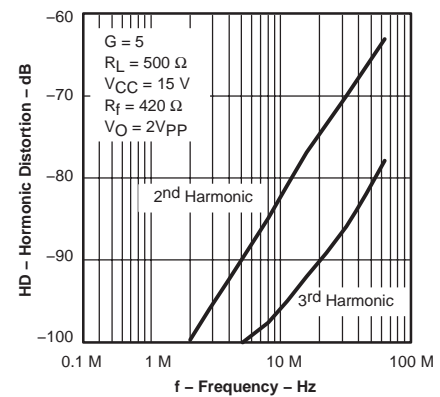


Figure 24

**HARMONIC DISTORTION
VS
FREQUENCY**

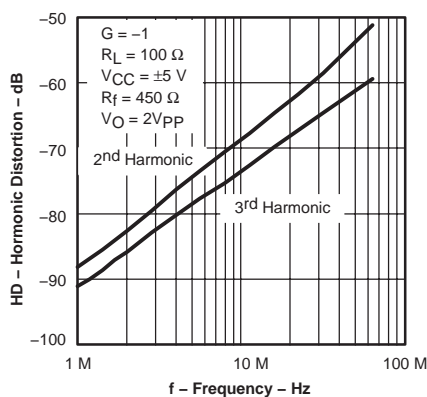


Figure 25

**HARMONIC DISTORTION
VS
FREQUENCY**

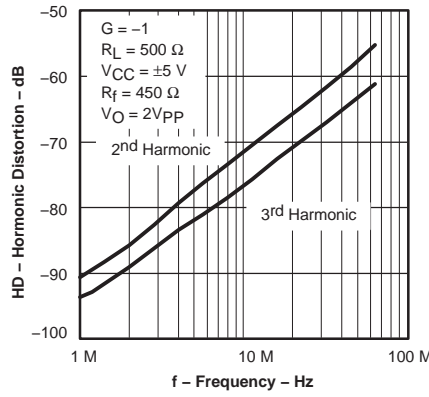


Figure 26

**HARMONIC DISTORTION
VS
FREQUENCY**

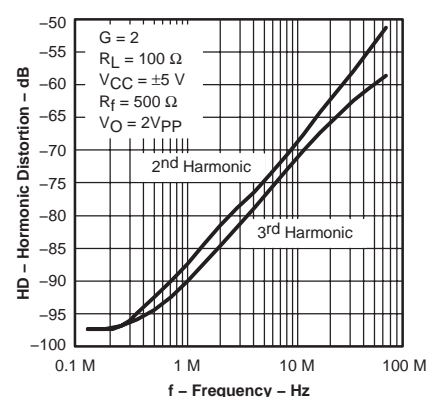


Figure 27

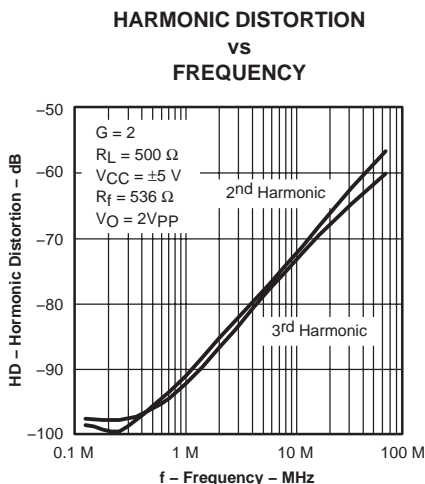


Figure 28

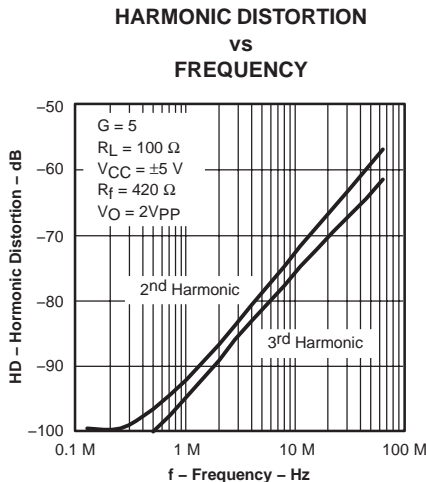


Figure 29

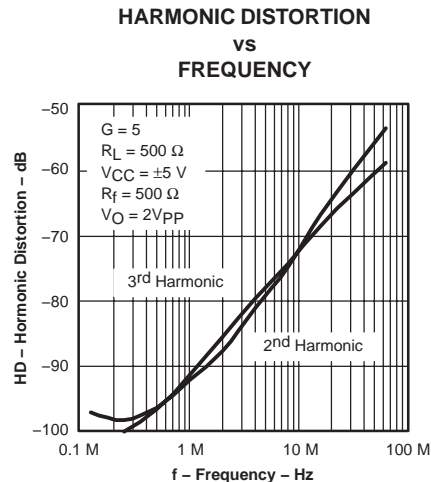


Figure 30

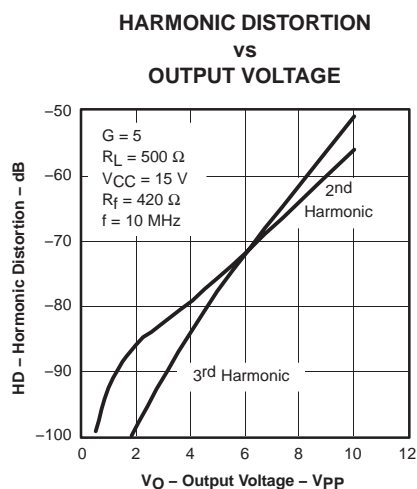


Figure 31

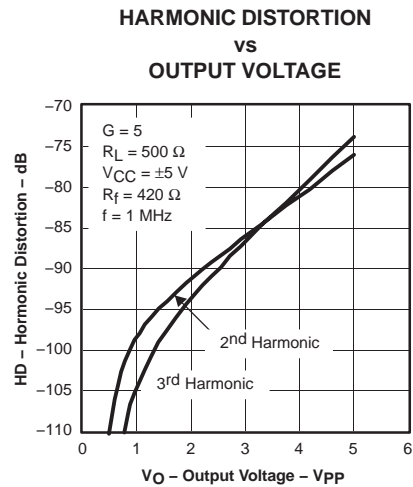


Figure 32

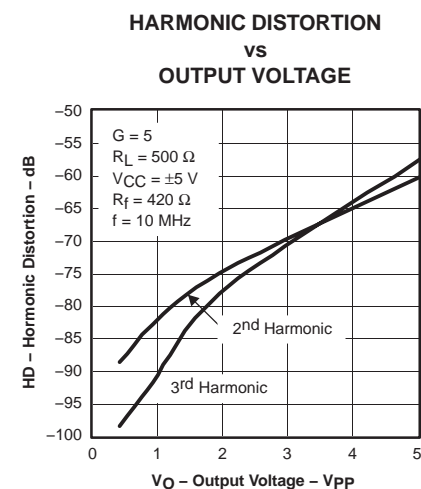


Figure 33

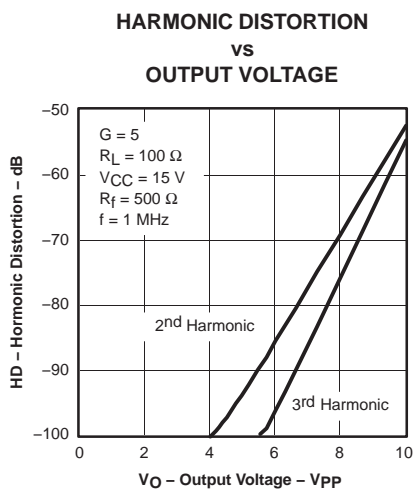


Figure 34

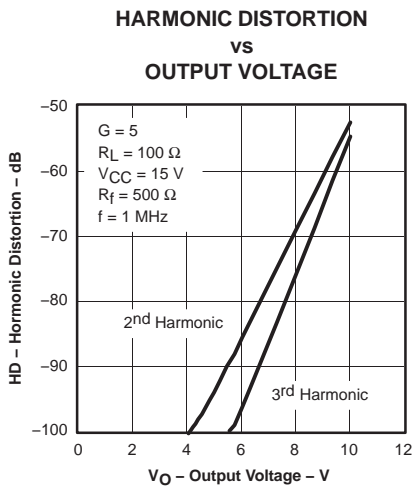


Figure 35

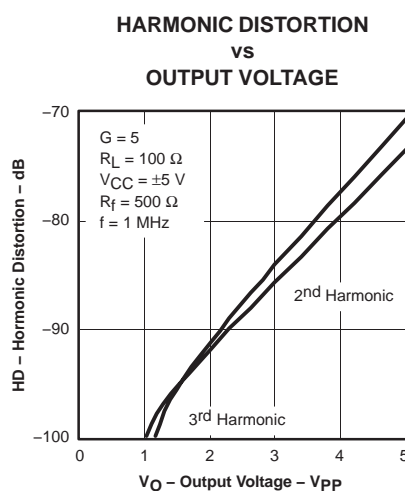


Figure 36

**HARMONIC DISTORTION
vs
OUTPUT VOLTAGE**

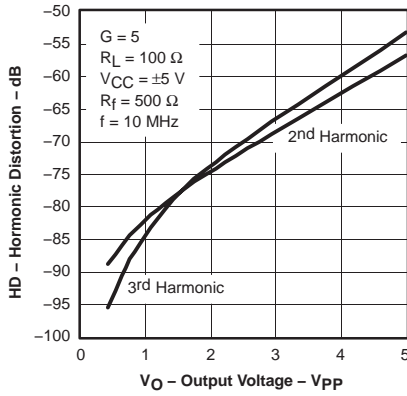


Figure 37

**HARMONIC DISTORTION
vs
OUTPUT VOLTAGE**

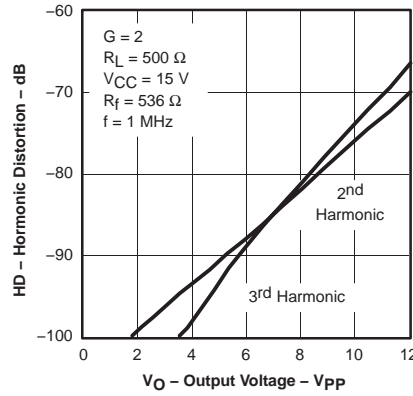


Figure 38

**HARMONIC DISTORTION
vs
OUTPUT VOLTAGE**

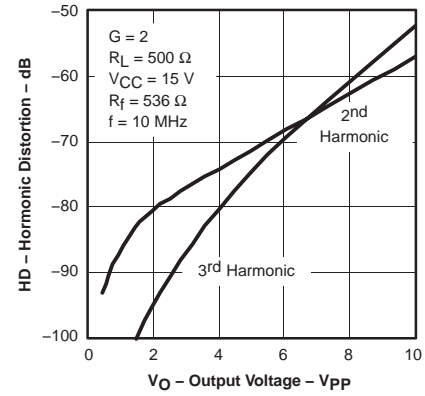


Figure 39

**HARMONIC DISTORTION
vs
OUTPUT VOLTAGE**

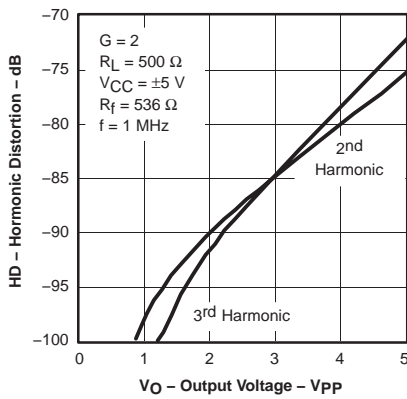


Figure 40

**HARMONIC DISTORTION
vs
OUTPUT VOLTAGE**

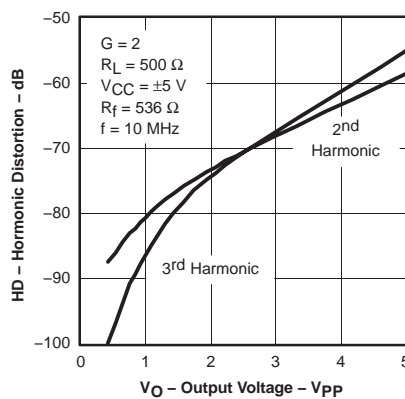


Figure 41

**HARMONIC DISTORTION
vs
OUTPUT VOLTAGE**

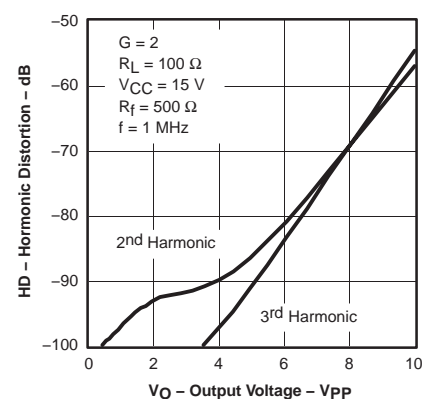


Figure 42

**HARMONIC DISTORTION
vs
OUTPUT VOLTAGE**

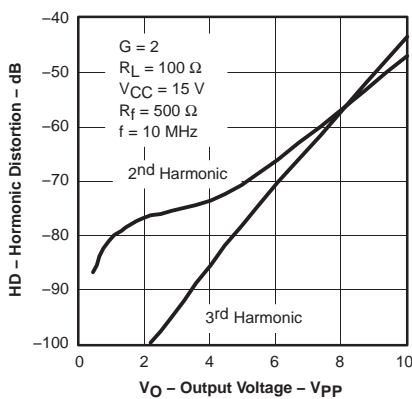


Figure 43

**HARMONIC DISTORTION
vs
OUTPUT VOLTAGE**

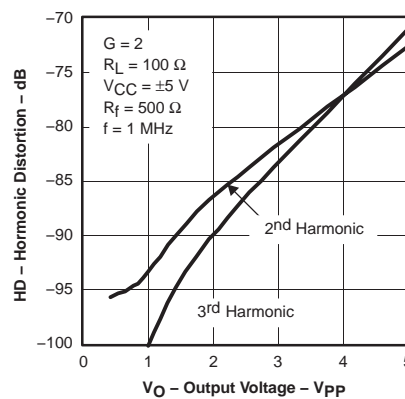


Figure 44

**HARMONIC DISTORTION
vs
OUTPUT VOLTAGE**

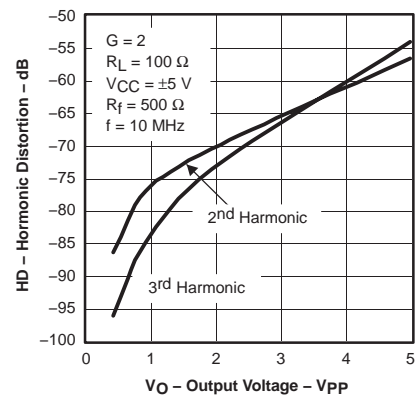


Figure 45

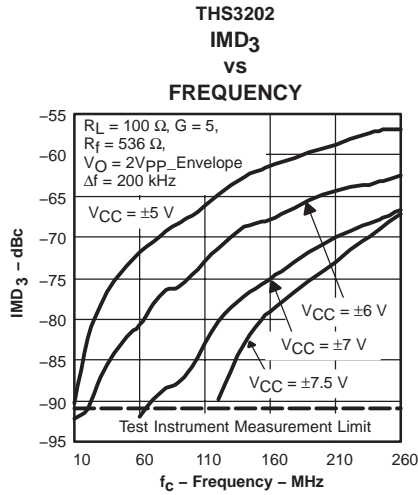


Figure 46

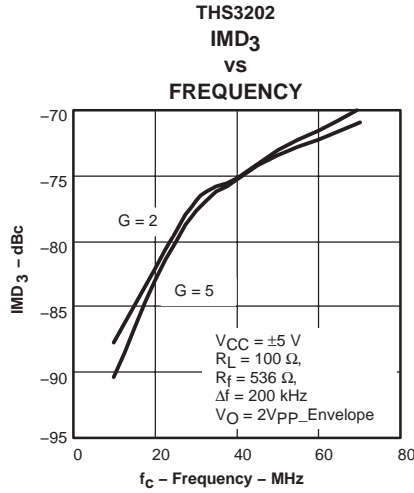


Figure 47

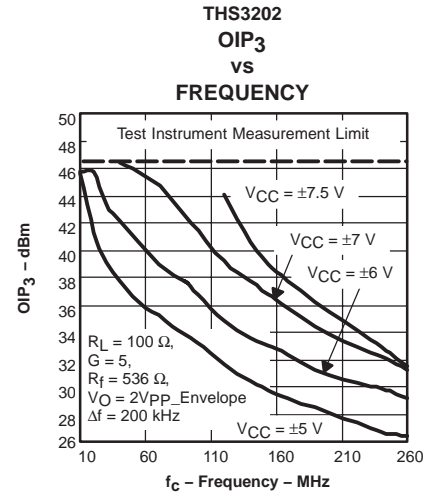


Figure 48

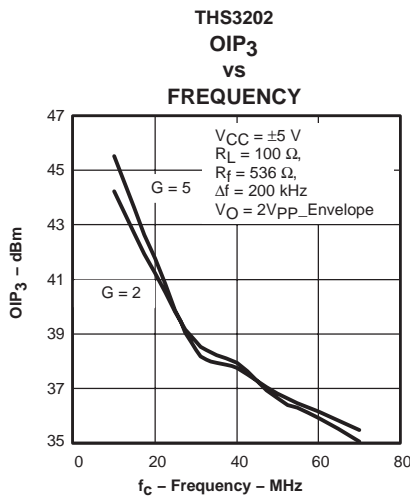
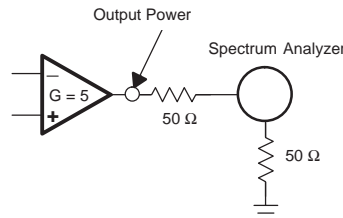


Figure 49

**TEST CIRCUIT FOR
IMD₃ / OIP₃**



This circuit applies to figures 46 through 49

Figure 50

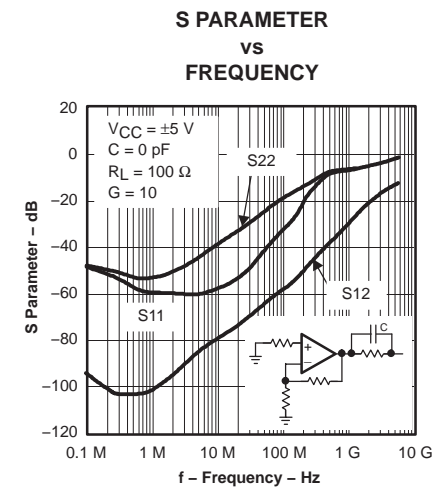


Figure 51

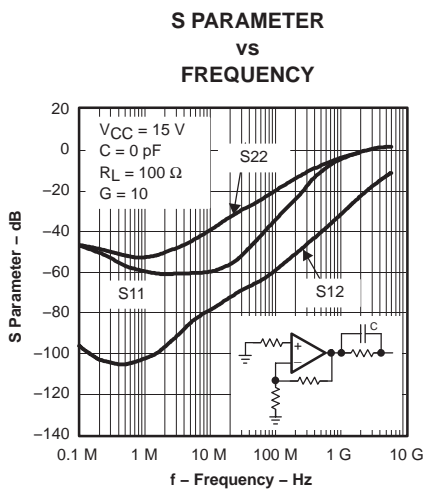


Figure 52

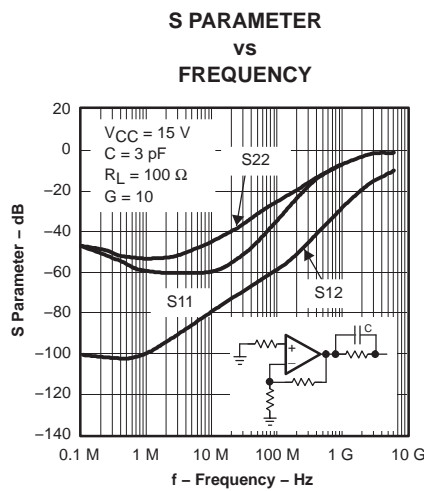


Figure 53

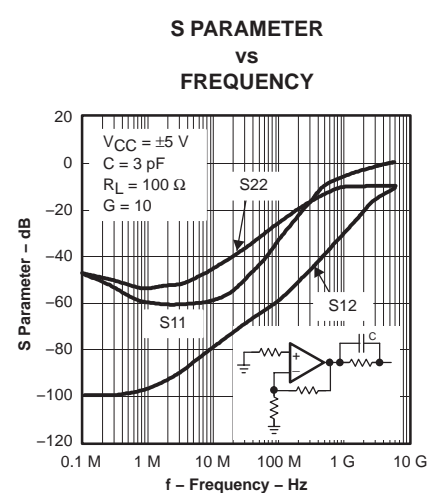


Figure 54

**INPUT CURRENT NOISE DENSITY
VS
FREQUENCY**

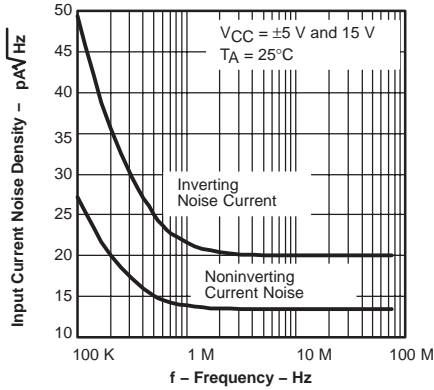


Figure 55

**VOLTAGE NOISE DENSITY
VS
FREQUENCY**

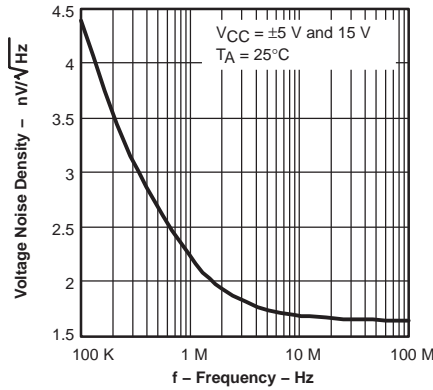


Figure 56

**TRANSIMPEDANCE
VS
FREQUENCY**

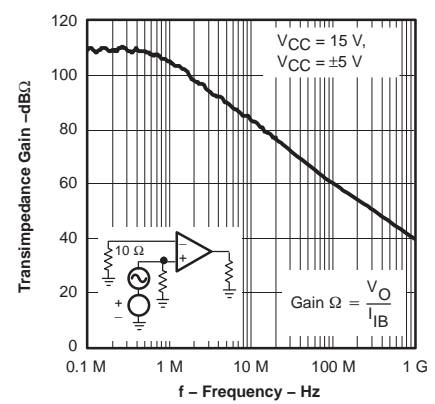


Figure 57

**OUTPUT IMPEDANCE
VS
FREQUENCY**

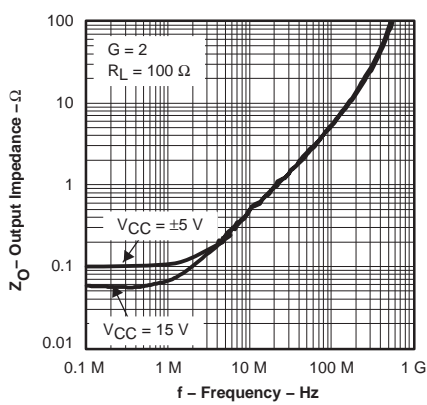


Figure 58

**THS3202
IMPEDANCE OF INVERTING INPUT**

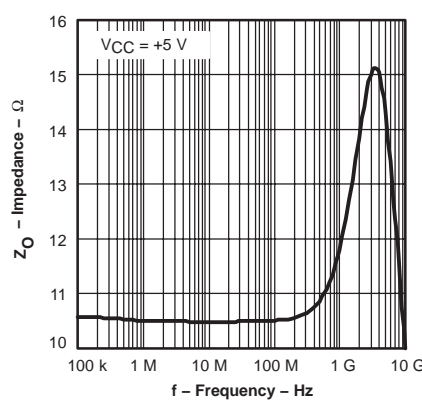


Figure 59

**SUPPLY CURRENT/CHANNEL
VS
SUPPLY VOLTAGE**

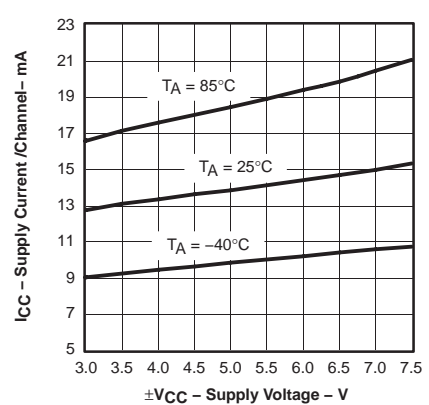


Figure 60

**INPUT OFFSET VOLTAGE
VS
FREE-AIR TEMPERATURE**

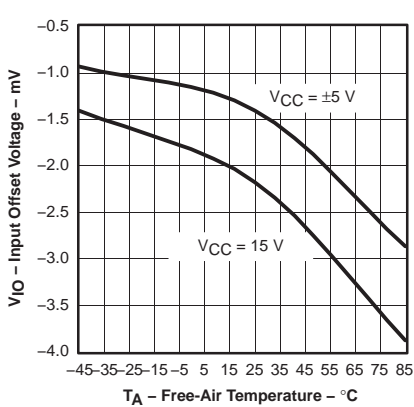


Figure 61

**OFFSET VOLTAGE
VS
COMMON-MODE INPUT VOLTAGE RANGE**

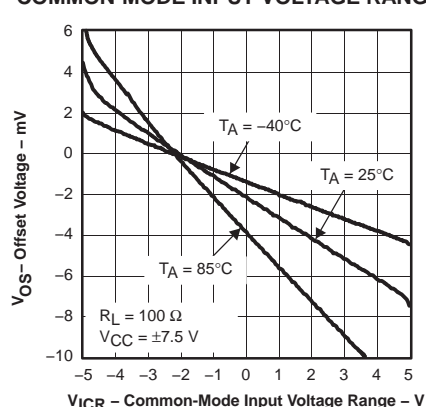


Figure 62

**INPUT BIAS CURRENT
VS
FREE-AIR TEMPERATURE**

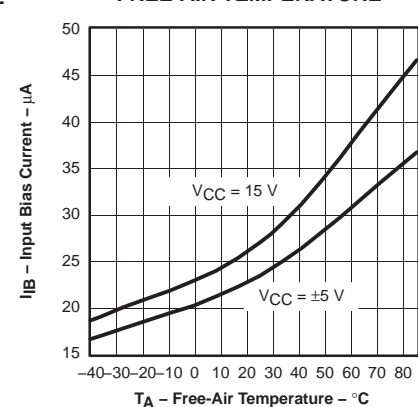


Figure 63

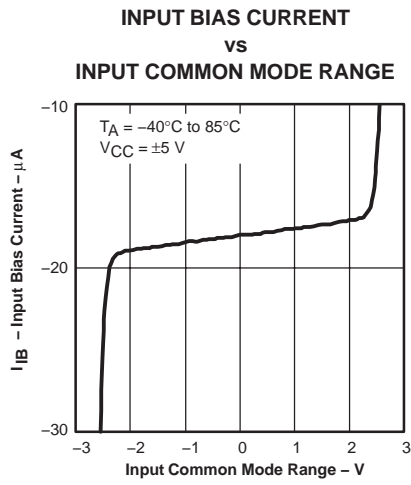


Figure 64

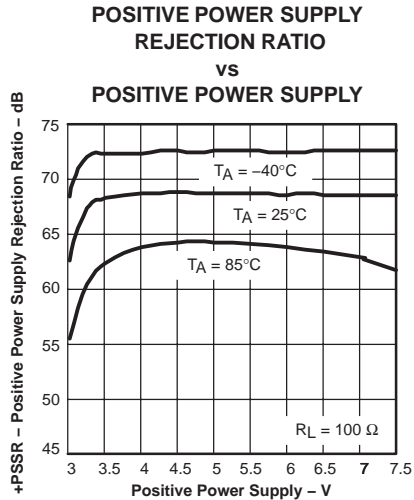


Figure 65

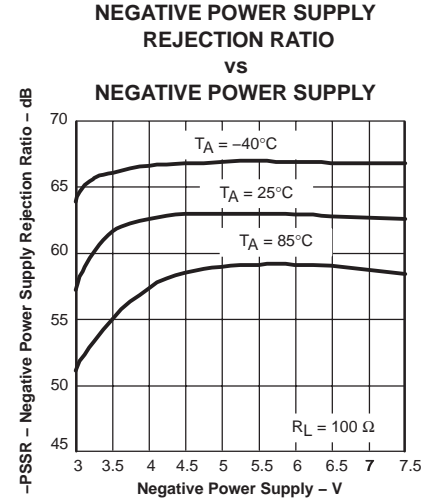


Figure 66

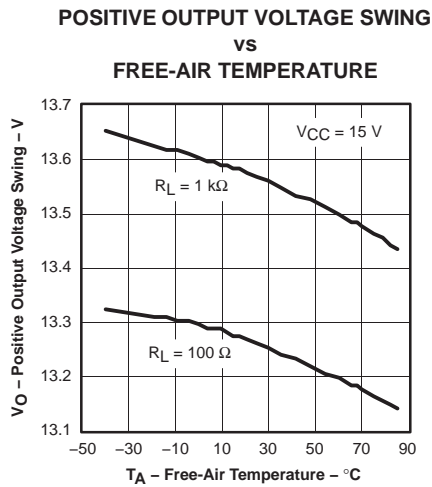


Figure 67

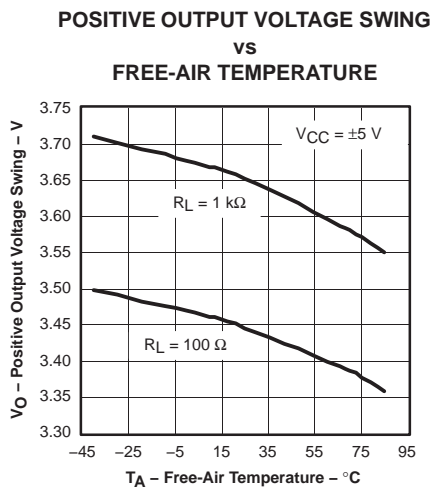


Figure 68

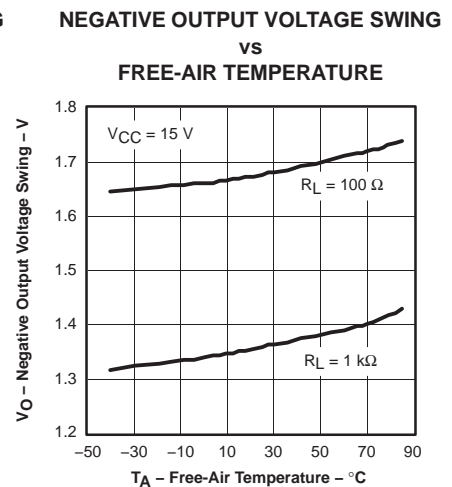


Figure 69

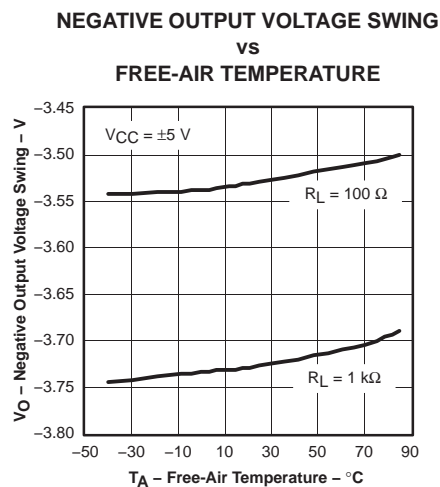


Figure 70

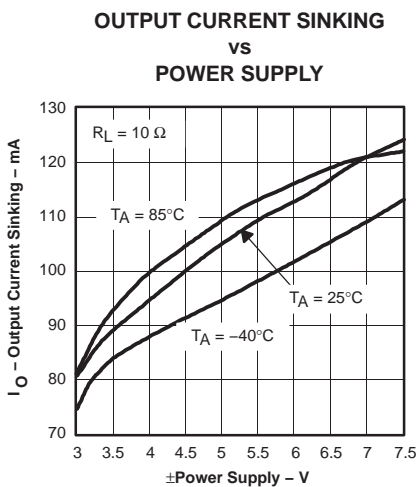


Figure 71

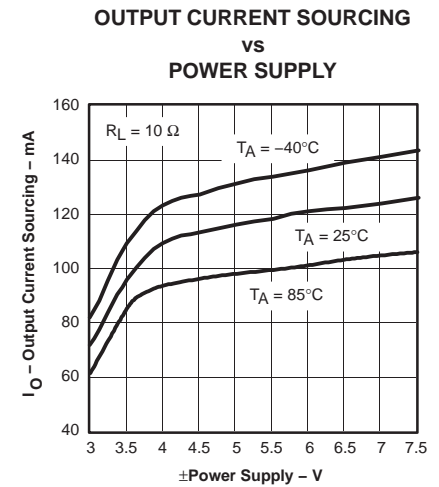


Figure 72

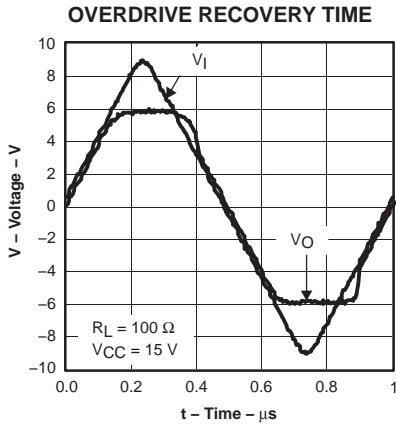


Figure 73

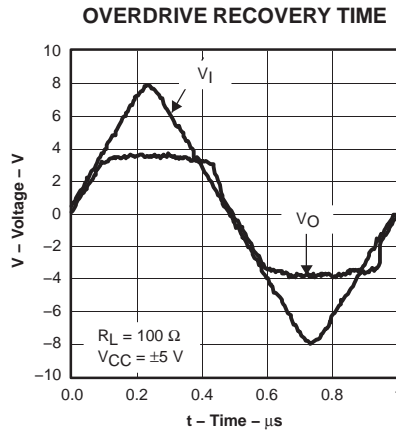


Figure 74

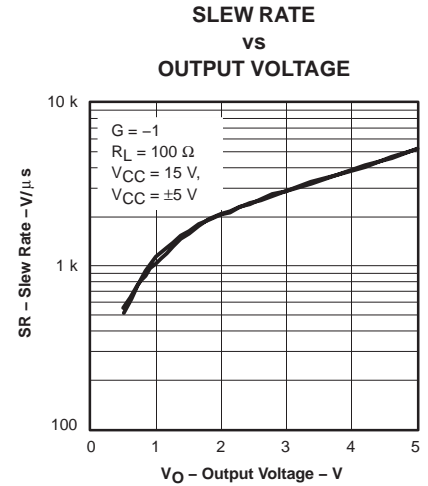


Figure 75

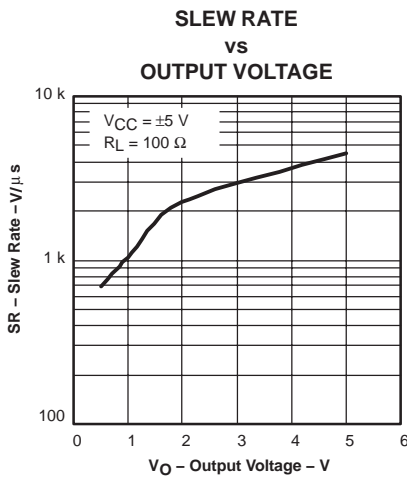


Figure 76

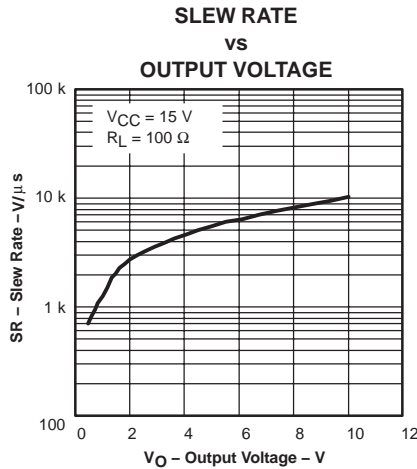


Figure 77

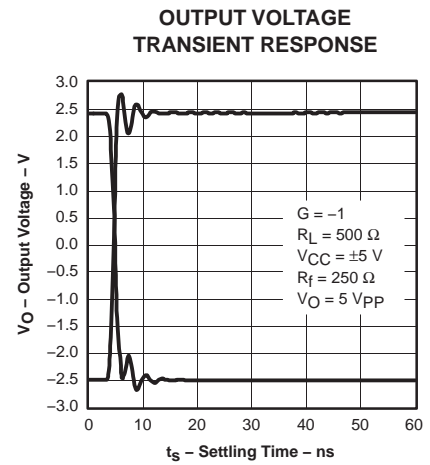


Figure 78

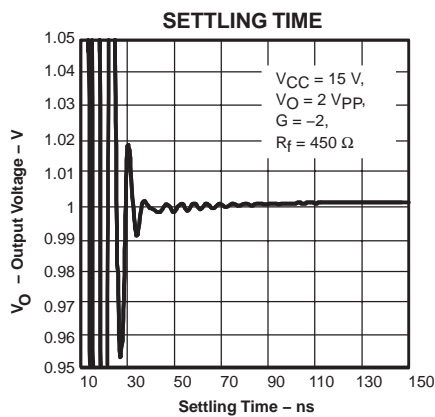


Figure 79

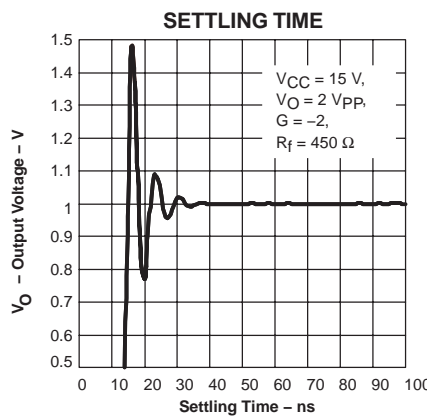


Figure 80

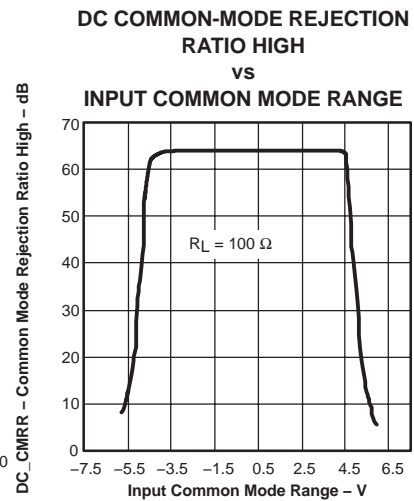


Figure 81

**POWER SUPPLY REJECTION RATIO
vs
FREQUENCY**

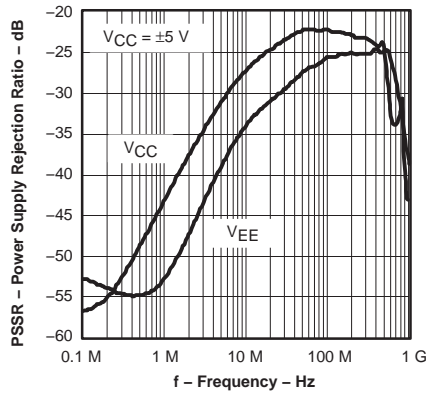


Figure 82

**POWER SUPPLY REJECTION RATIO
vs
FREQUENCY**

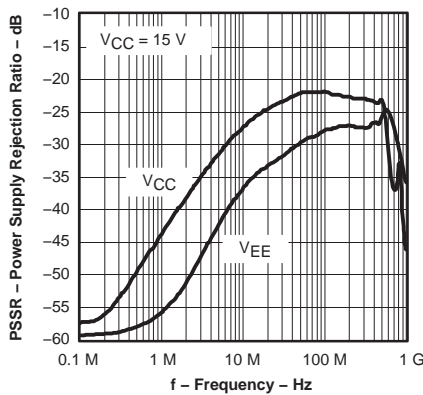


Figure 83

**DIFFERENTIAL GAIN ERROR
vs
150-Ω LOADS**

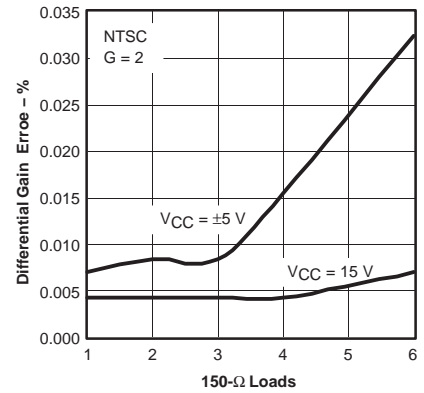


Figure 84

**DIFFERENTIAL GAIN ERROR
vs
150-Ω LOADS**

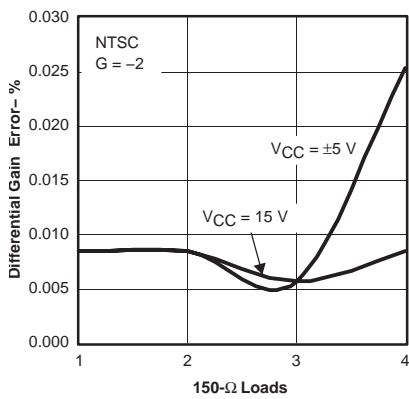


Figure 85

**DIFFERENTIAL PHASE ERROR
vs
150-Ω LOADS**

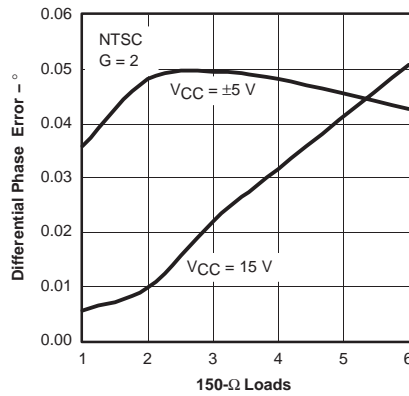


Figure 86

**DIFFERENTIAL PHASE ERROR
vs
150-Ω LOADS**

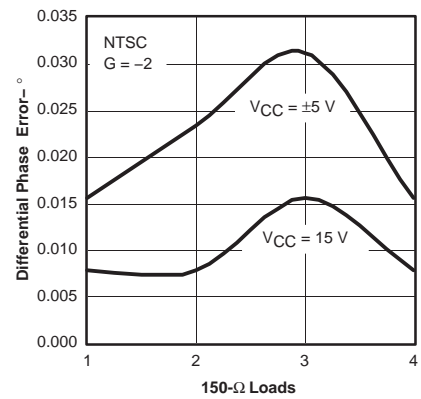


Figure 87

**DIFFERENTIAL GAIN ERROR
vs
150-Ω LOADS**

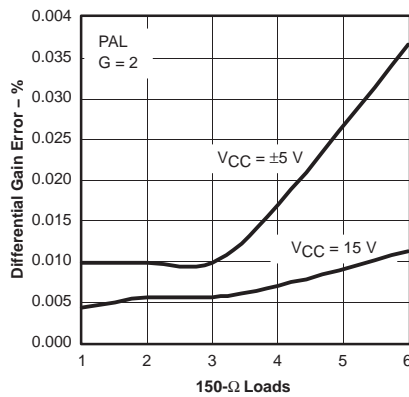


Figure 88

**DIFFERENTIAL PHASE ERROR
vs
150-Ω LOADS**

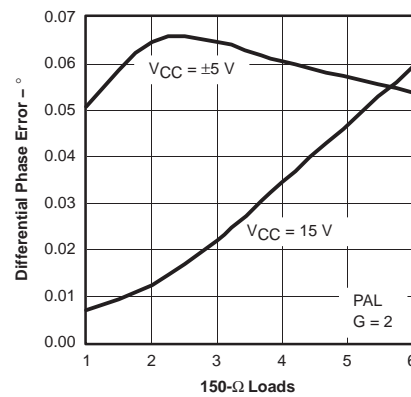


Figure 89

APPLICATION INFORMATION

INTRODUCTION

The THS3202 is a high-speed, operational amplifier configured in a current-feedback architecture. The device is built using Texas Instruments BiCOM–II process, a 15-V, dielectrically isolated, complementary bipolar process with NPN and PNP transistors possessing f_{TS} of several GHz. This configuration implements an exceptionally high-performance amplifier that has a wide bandwidth, high slew rate, fast settling time, and low distortion.

RECOMMENDED FEEDBACK AND GAIN RESISTOR VALUES

As with all current-feedback amplifiers, the bandwidth of the THS3202 is an inversely proportional function of the value of the feedback resistor. The recommended resistors for the optimum frequency response are shown in Table 1. These should be used as a starting point and once optimum values are found, 1% tolerance resistors should be used to maintain frequency response characteristics. For most applications, a feedback resistor value of 750 Ω is recommended—a good compromise between bandwidth and phase margin that yields a very stable amplifier.

Table 1. Recommended Resistor Values for Optimum Frequency Response

THS3202 R_F for AC When $R_{load} = 100 \Omega$			
GAIN	V_{sup}	Peaking	R_F Value
1	15	Optimum	619
	± 5	Optimum	619
2	15	Optimum	536
	± 5	Optimum	536
5	15	Optimum	402
	± 5	Optimum	402
10	15	Optimum	200
	± 5	Optimum	200
–1	15	Optimum	450
	± 5	Optimum	450

As shown in Table 1, to maintain the highest bandwidth with an increasing gain, the feedback resistor is reduced. The advantage of dropping the feedback resistor (and the gain resistor) is the noise of the system is also reduced compared to no reduction of these resistor values, see noise calculations section. Thus, keeping the bandwidth as high as possible maintains very good distortion performance of the amplifier by keeping the excess loop gain as high as possible.

Care must be taken to not drop these values too low. The amplifier's output must drive the feedback resistance (and gain resistance) and may place a burden on the amplifier. The end result is that distortion may actually increase due to the low impedance load presented to the amplifier. Careful management of the amplifier bandwidth and the associated loading effects needs to be examined by the designer for optimum performance.

The THS3202 amplifier exhibit very good distortion performance and bandwidth with the capability of utilizing up to 15 V power supplies. Their excellent current drive capability of up to 115 mA driving into a 20- Ω load allows for many versatile applications. One application is driving a twisted pair line (i.e., telephone line). Figure 90 shows a simple circuit for driving a twisted pair differentially.

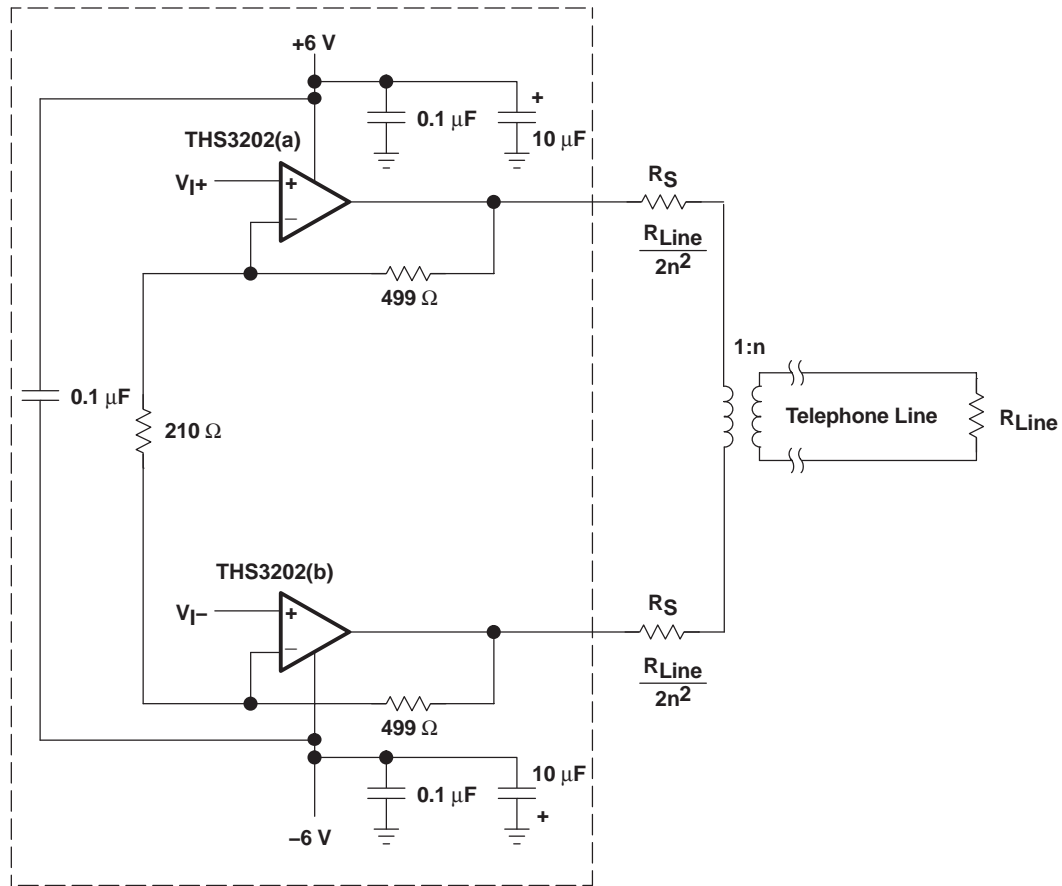


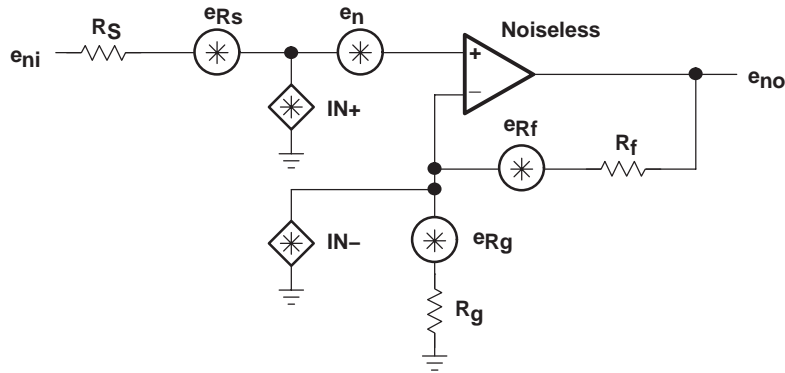
Figure 90. Simple Line Driver With THS3202

Due to the large power supply voltages and the large current drive capability, power dissipation of the amplifier must not be neglected. To have as much power dissipation as possible in a small package, the THS3202 is available only in a MSOP–8 PowerPAD package (DGN) and SOIC–8 package (D). Again, power dissipation of the amplifier must be carefully examined or else the amplifiers could become too hot and performance can be severely degraded. See the *Power Dissipation and Thermal Considerations* section for more information on thermal management.

NOISE CALCULATIONS

Noise can cause errors on very small signals. This is especially true for amplifying small signals coming over a transmission line or an antenna. The noise model for current-feedback amplifiers (CFB) is the same as for voltage feedback amplifiers (VFB). The only difference between the two is that CFB amplifiers generally specify different current-noise parameters for each input, while VFB amplifiers usually only specify one noise-current parameter. The noise model is shown in Figure 91. This model includes all of the noise sources as follows:

- e_n = Amplifier internal voltage noise (nV/\sqrt{Hz})
- IN_+ = Noninverting current noise (pA/\sqrt{Hz})
- IN_- = Inverting current noise (pA/\sqrt{Hz})
- e_{RX} = Thermal voltage noise associated with each resistor ($e_{RX} = 4 kTR_x$)


Figure 91. Noise Model

The total equivalent input noise density (e_{ni}) is calculated by using the following equation:

$$e_{ni} = \sqrt{(e_n)^2 + (IN_+ \times R_S)^2 + (IN_- \times (R_f \parallel R_g))^2 + 4kTR_S + 4kT(R_f \parallel R_g)}$$

where:

- k = Boltzmann's constant = 1.380658×10^{-23}
- T = Temperature in degrees Kelvin (273 + °C)
- $R_f \parallel R_g$ = Parallel resistance of R_f and R_g

To get the equivalent output noise of the amplifier, just multiply the equivalent input noise density (e_{ni}) by the overall amplifier gain (A_V).

$$e_{no} = e_{ni} A_V = e_{ni} \left(1 + \frac{R_f}{R_g} \right) \text{ (Noninverting Case)}$$

As the previous equations show, to keep noise at a minimum, small value resistors should be used. As the closed-loop gain is increased (by reducing R_f and R_g), the input noise is reduced considerably because of the parallel resistance term. This leads to the general conclusion that the most dominant noise sources are the source resistor (R_S) and the internal amplifier noise voltage (e_n). Because noise is summed in a root-mean-squares method, noise sources smaller than 25% of the largest noise source can be effectively ignored. This can greatly simplify the formula and make noise calculations much easier.

This brings up another noise measurement usually preferred in RF applications, the noise figure (NF). Noise figure is a measure of noise degradation caused by the amplifier. The value of the source resistance must be defined and is typically 50 Ω in RF applications.

$$NF = 10 \log \left[\frac{e_{ni}^2}{e_{Rs}^2} \right]$$

Because the dominant noise components are generally the source resistance and the internal amplifier noise voltage, we can approximate noise figure as:

$$NF = 10 \log \left[1 + \frac{\left[(e_n)^2 + (IN_+ \times R_S)^2 \right]}{4kTR_S} \right]$$

PRINTED-CIRCUIT BOARD LAYOUT TECHNIQUES FOR OPTIMAL PERFORMANCE

Achieving optimum performance with high frequency amplifier-like devices in the THS320x family requires careful attention to board layout parasitic and external component types.

Recommendations that optimize performance include:

- Minimize parasitic capacitance to any ac ground for all of the signal I/O pins. Parasitic capacitance on the output and input pins can cause instability. To reduce unwanted capacitance, a window around the signal I/O pins should be opened in all of the ground and power planes around those pins. Otherwise, ground and power planes should be unbroken elsewhere on the board.
- Minimize the distance ($< 0.25''$) from the power supply pins to high frequency $0.1\text{-}\mu\text{F}$ and 100 pF decoupling capacitors. At the device pins, the ground and power plane layout should not be in close proximity to the signal I/O pins. Avoid narrow power and ground traces to minimize inductance between the pins and the decoupling capacitors. The power supply connections should always be decoupled with these capacitors. Larger ($6.8\text{ }\mu\text{F}$ or more) tantalum decoupling capacitors, effective at lower frequency, should also be used on the main supply pins. These may be placed somewhat farther from the device and may be shared among several devices in the same area of the PC board. The primary goal is to minimize the impedance seen in the differential-current return paths. For driving differential loads with the THS3202, adding a capacitor between the power supply pins improves 2nd order harmonic distortion performance. This also minimizes the current loop formed by the differential drive.
- Careful selection and placement of external components preserve the high frequency performance of the THS320x family. Resistors should be a very low reactance type. Surface-mount resistors work best and allow a tighter overall layout. Again, keep their leads and PC board trace length as short as possible. Never use wirebound type resistors in a high frequency application. Since the output pin and inverting input pins are the most sensitive to parasitic capacitance, always position the feedback and series output resistors, if any, as close as possible to the inverting input pins and output pins. Other network components, such as input termination resistors, should be placed close to the gain-setting resistors. Even with a low parasitic capacitance shunting the external resistors, excessively high resistor values can create significant time constants that can degrade performance. Good axial metal-film or surface-mount resistors have approximately 0.2 pF in shunt with the resistor. For resistor values $> 2.0\text{ k}\Omega$, this parasitic capacitance can add a pole and/or a zero that can effect circuit operation. Keep resistor values as low as possible, consistent with load driving considerations.
- Connections to other wideband devices on the board may be made with short direct traces or through onboard transmission lines. For short connections, consider the trace and the input to the next device as a lumped capacitive load. Relatively wide traces (50 mils to 100 mils) should be used, preferably with ground and power planes opened up around them. Estimate the total capacitive load and determine if isolation resistors on the outputs are necessary. Low parasitic capacitive loads ($< 4\text{ pF}$) may not need an R_S since the THS320x family is nominally compensated to operate with a 2-pF parasitic load. Higher parasitic capacitive loads without an R_S are allowed as the signal gain increases (increasing the unloaded phase margin). If a long trace is required, and the 6-dB signal loss intrinsic to a doubly-terminated transmission line is acceptable, implement a matched impedance transmission line using microstrip or stripline techniques (consult an ECL design handbook for microstrip and stripline layout techniques).

A $50\text{-}\Omega$ environment is not necessary onboard, and in fact, a higher impedance environment improves distortion as shown in the distortion versus load plots. With a characteristic board trace impedance based on board material and trace dimensions, a matching series resistor into the trace from the output of the THS320x is used as well as a terminating shunt resistor at the input of the destination device.

Remember also that the terminating impedance is the parallel combination of the shunt resistor and the input impedance of the destination device: this total effective impedance should be set to match the trace impedance. If the 6-dB attenuation of a doubly terminated transmission line is unacceptable, a long trace can be series-terminated at the source end only. Treat the trace as a capacitive load in this case. This does not preserve signal integrity as well as a doubly-terminated line. If the input impedance of the destination device is low, there is some signal attenuation due to the voltage divider formed by the series output into the terminating impedance.

- Socketing a high speed part like the THS320x family is not recommended. The additional lead length and pin-to-pin capacitance introduced by the socket can create an extremely troublesome parasitic network which can make it almost impossible to achieve a smooth, stable frequency response. Best results are obtained by soldering the THS320x family parts directly onto the board.

PowerPAD DESIGN CONSIDERATIONS

The THS320x family is available in a thermally-enhanced PowerPAD family of packages. These packages are constructed using a downset leadframe upon which the die is mounted [see Figure 92(a) and Figure 92(b)]. This arrangement results in the lead frame being exposed as a thermal pad on the underside of the package [see Figure 92(c)]. Because this thermal pad has direct thermal contact with the die, excellent thermal performance can be achieved by providing a good thermal path away from the thermal pad.

The PowerPAD package allows for both assembly and thermal management in one manufacturing operation. During the surface-mount solder operation (when the leads are being soldered), the thermal pad can also be soldered to a copper area underneath the package. Through the use of thermal paths within this copper area, heat can be conducted away from the package into either a ground plane or other heat dissipating device.

The PowerPAD package represents a breakthrough in combining the small area and ease of assembly of surface mount with the, heretofore, awkward mechanical methods of heatsinking.

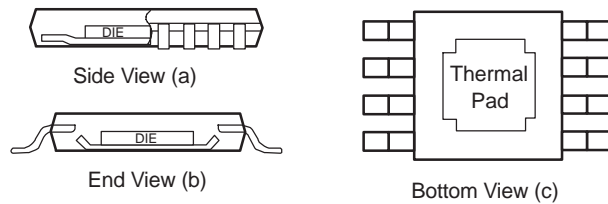


Figure 92. Views of Thermally Enhanced Package

Although there are many ways to properly heatsink the PowerPAD package, the following steps illustrate the recommended approach.

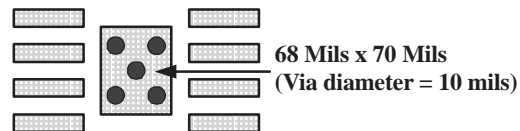


Figure 93. DGN PowerPAD PCB Etch and Via Pattern

PowerPAD PCB LAYOUT CONSIDERATIONS

1. Prepare the PCB with a top side etch pattern as shown in Figure 93. There should be etch for the leads as well as etch for the thermal pad.
2. Place five holes in the area of the thermal pad. These holes should be 10 mils in diameter. Keep them small so that solder wicking through the holes is not a problem during reflow.
3. Additional vias may be placed anywhere along the thermal plane outside of the thermal pad area. This helps dissipate the heat generated by the THS320x family IC. These additional vias may be larger than the 10-mil diameter vias directly under the thermal pad. They can be larger because they are not in the thermal pad area to be soldered so that wicking is not a problem.
4. Connect all holes to the internal ground plane.
5. When connecting these holes to the ground plane, **do not** use the typical web or spoke via connection methodology. Web connections have a high thermal resistance connection that is useful for slowing the heat transfer during soldering operations. This makes the soldering of vias that have plane connections easier. In this application, however, low thermal resistance is desired for the most efficient heat transfer. Therefore, the holes under the THS320x family PowerPAD package should make their connection to the internal ground plane with a complete connection around the entire circumference of the plated-through hole.
6. The top-side solder mask should leave the terminals of the package and the thermal pad area with its five holes exposed. The bottom-side solder mask should cover the five holes of the thermal pad area. This prevents solder from being pulled away from the thermal pad area during the reflow process.
7. Apply solder paste to the exposed thermal pad area and all of the IC terminals.
8. With these preparatory steps in place, the IC is simply placed in position and run through the solder reflow operation as any standard surface-mount component. This results in a part that is properly installed.

POWER DISSIPATION AND THERMAL CONSIDERATIONS

To maintain maximum output capabilities, the THS3202 does not incorporate automatic thermal shutoff protection. The designer must take care to ensure that the design does not violate the absolute maximum junction temperature of the device. Failure may result if the absolute maximum junction temperature of 150°C is exceeded. For best performance, design for a maximum junction temperature of 125°C. Between 125°C and 150°C, damage does not occur, but the performance of the amplifier begins to degrade.

The thermal characteristics of the device are dictated by the package and the PC board. Maximum power dissipation for a given package can be calculated using the following formula.

$$P_{Dmax} = \frac{T_{max} - T_A}{\theta_{JA}}$$

where:

P_{Dmax} is the maximum power dissipation in the amplifier (W).

T_{max} is the absolute maximum junction temperature (°C).

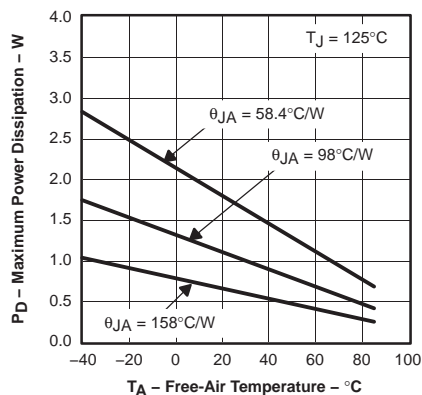
T_A is the ambient temperature (°C).

$\theta_{JA} = \theta_{JC} + \theta_{CA}$

θ_{JC} is the thermal coefficient from the silicon junctions to the case (°C/W).

θ_{CA} is the thermal coefficient from the case to ambient air (°C/W).

For systems where heat dissipation is more critical, the THS320x family of devices is offered in an 8-pin MSOP with PowerPAD and the THS3202 is available in the SOIC-8 PowerPAD package offering even better thermal performance. The thermal coefficient for the PowerPAD packages are substantially improved over the traditional SOIC. Maximum power dissipation levels are depicted in the graph for the available packages. The data for the PowerPAD packages assume a board layout that follows the PowerPAD layout guidelines referenced above and detailed in the PowerPAD application note number SLMA002. The following graph also illustrates the effect of not soldering the PowerPAD to a PCB. The thermal impedance increases substantially which may cause serious heat and performance issues. Be sure to always solder the PowerPAD to the PCB for optimum performance.



Results are With No Air Flow and PCB Size = 3"x3"
 $\theta_{JA} = 58.4^{\circ}\text{C/W}$ for 8-Pin MSOP w/PowerPad (DGN)
 $\theta_{JA} = 98^{\circ}\text{C/W}$ for 8-Pin SOIC High Test PCB (D)
 $\theta_{JA} = 158^{\circ}\text{C/W}$ for 8-Pin MSOP w/PowerPad w/o Solder

Figure 94. Maximum Power Dissipation vs Ambient Temperature

When determining whether or not the device satisfies the maximum power dissipation requirement, it is important to not only consider quiescent power dissipation, but also dynamic power dissipation. Often times, this is difficult to quantify because the signal pattern is inconsistent, but an estimate of the RMS power dissipation can provide visibility into a possible problem.

DRIVING A CAPACITIVE LOAD

Driving capacitive loads with high-performance amplifiers is not a problem as long as certain precautions are taken. The first is to realize that the THS3202 has been internally compensated to maximize its bandwidth and slew-rate performance. When the amplifier is compensated in this manner, capacitive loading directly on the output decreases the device's phase margin leading to high-frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10 pF, it is recommended that a resistor be placed in series with the output of the amplifier, as shown in Figure 95. A minimum value of 10 Ω should work well for most applications. For example, in 75- Ω transmission systems, setting the series resistor value to 75 Ω both isolates any capacitance loading and provides the proper line impedance matching at the source end.

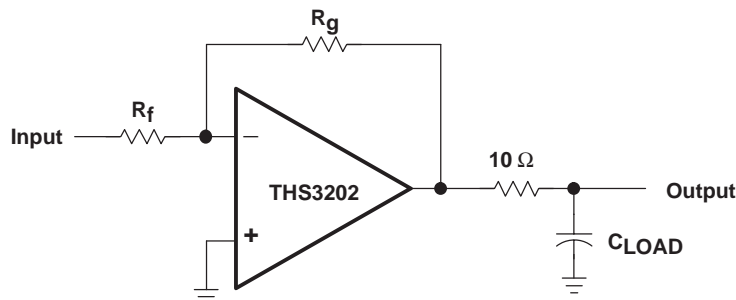


Figure 95. Driving a Capacitive Load

GENERAL CONFIGURATIONS

A common error for the first-time CFB user is creating a unity gain buffer amplifier by shorting the output directly to the inverting input. A CFB amplifier in this configuration oscillates and is *not* recommended. The THS3202, like all CFB amplifiers, *must* have a feedback resistor for stable operation. Additionally, placing capacitors directly from the output to the inverting input is not recommended. This is because, at high frequencies, a capacitor has a very low impedance. This results in an unstable amplifier and should not be considered when using a current-feedback amplifier. Because of this, integrators and simple low-pass filters, which are easily implemented on a VFB amplifier, have to be designed slightly differently. If filtering is required, simply place an RC-filter at the noninverting terminal of the operational-amplifier (see Figure 96).

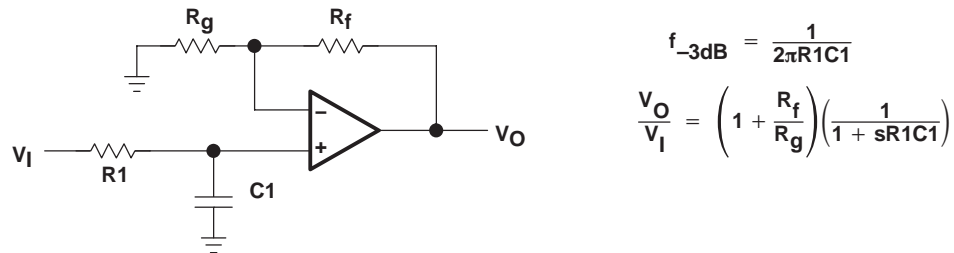


Figure 96. Single-Pole Low-Pass Filter

If a multiple-pole filter is required, the use of a Sallen-Key filter can work very well with CFB amplifiers. This is because the filtering elements are not in the negative feedback loop and stability is not compromised. Because of their high slew-rates and high bandwidths, CFB amplifiers can create very accurate signals and help minimize distortion. An example is shown in Figure 97.

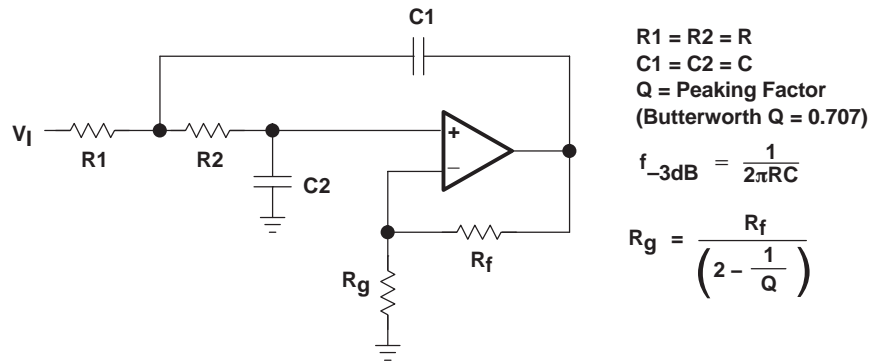


Figure 97. 2-Pole Low-Pass Sallen-Key Filter

THS3202

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There are two simple ways to create an integrator with a CFB amplifier. The first, shown in Figure 98, adds a resistor in series with the capacitor. This is acceptable because at high frequencies, the resistor is dominant and the feedback impedance never drops below the resistor value. The second, shown in Figure 99, uses positive feedback to create the integration. Caution is advised because oscillations can occur due to the positive feedback.

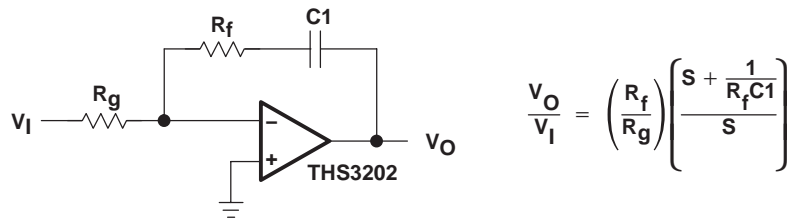


Figure 98. Inverting CFB Integrator

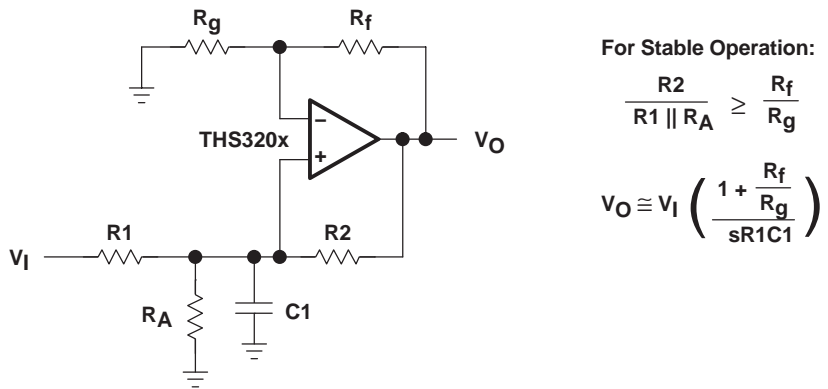


Figure 99. Noninverting CFB Integrator

The THS3202 may also be employed as a very good video distribution amplifier. One characteristic of distribution amplifiers is the fact that the differential phase (DP) and the differential gain (DG) are compromised as the number of lines increases and the closed-loop gain increases. Be sure to use termination resistors throughout the distribution system to minimize reflections and capacitive loading.

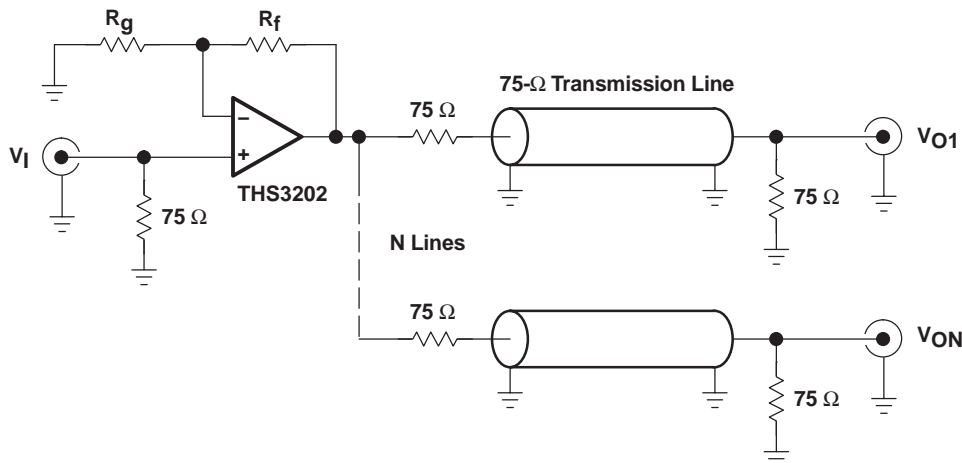
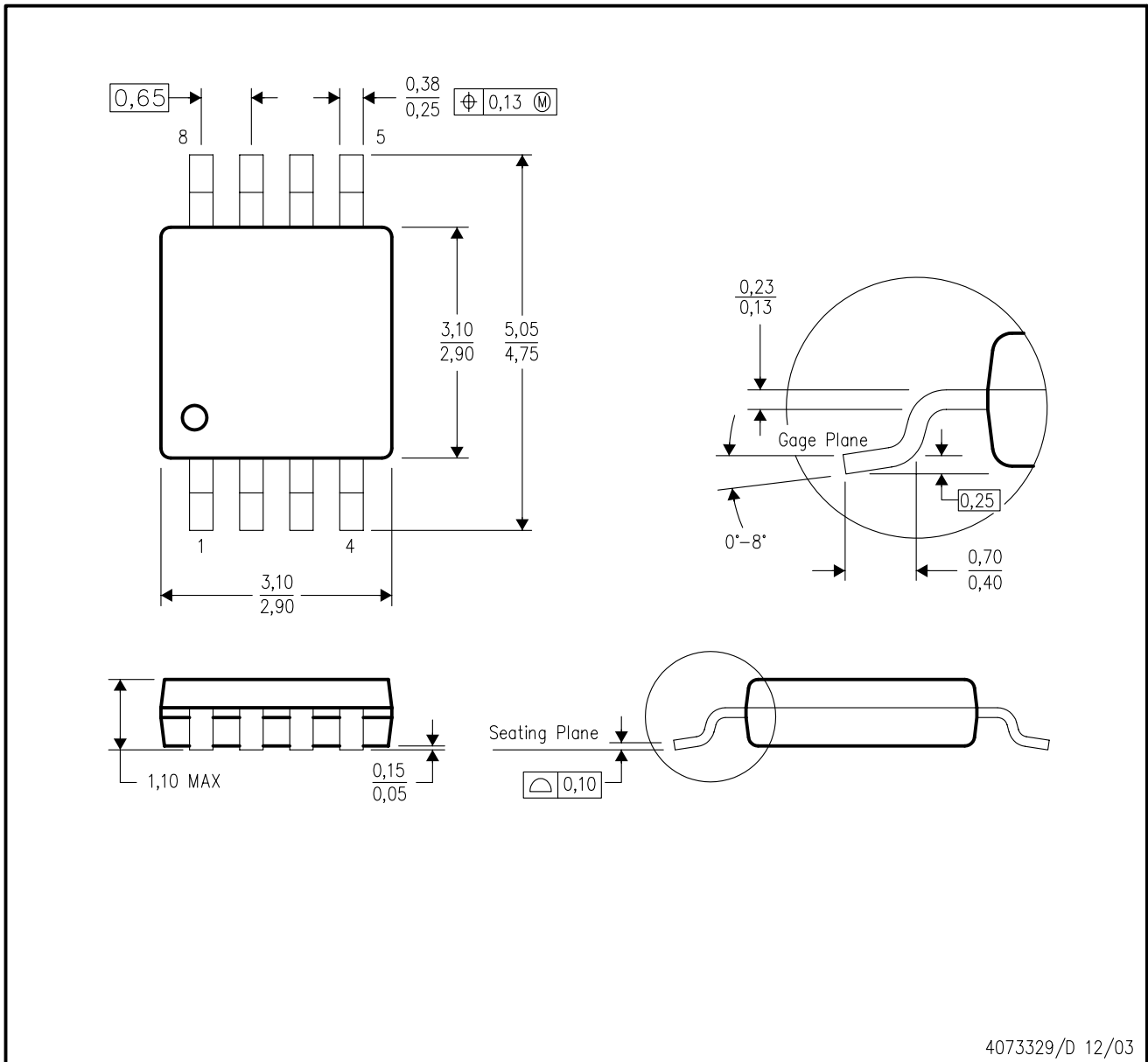


Figure 100. Video Distribution Amplifier Application

DGK (S-PDSO-G8)

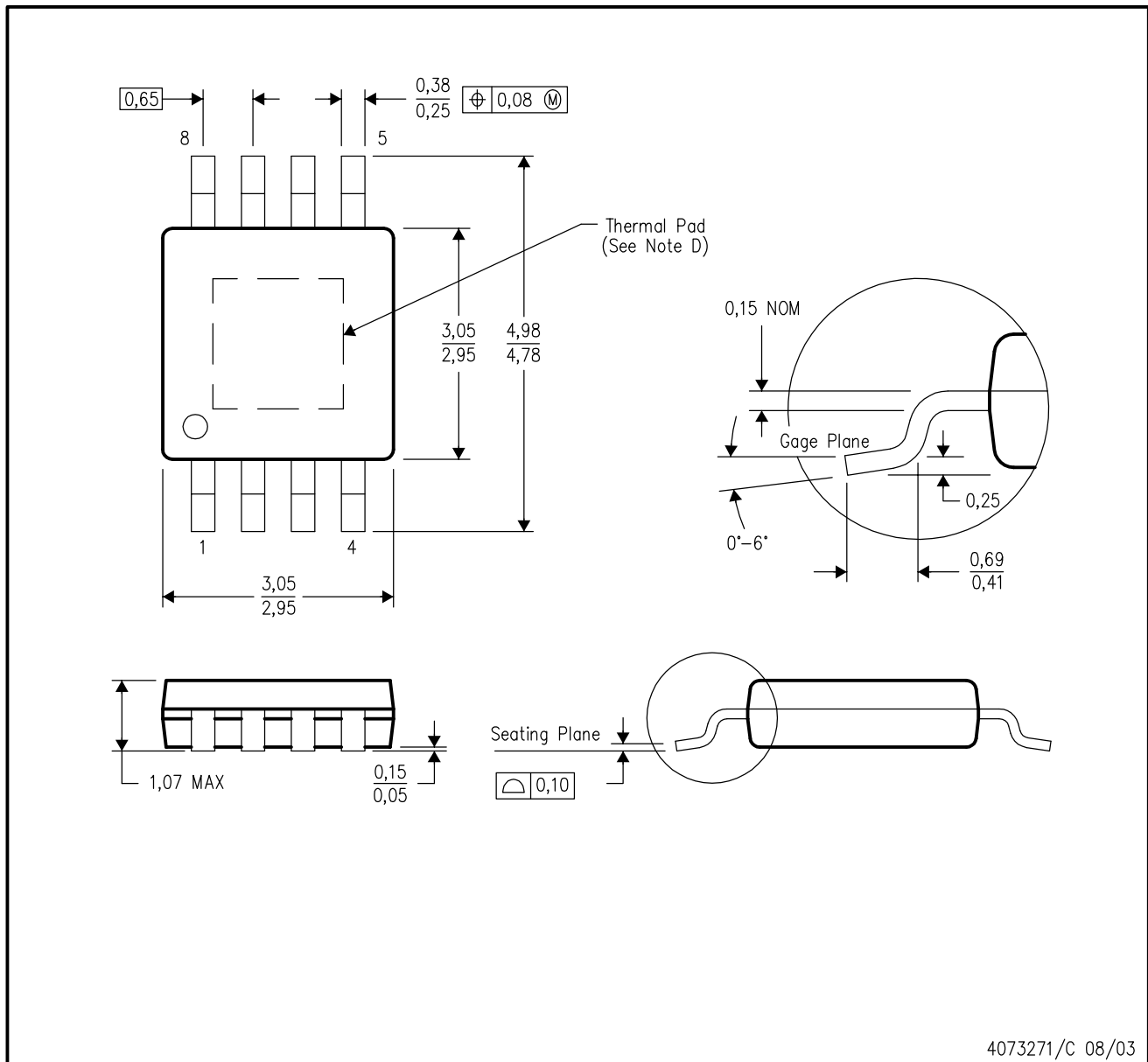
PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion.
 - D. Falls within JEDEC MO-187 variation AA.

DGN (S-PDSO-G8)

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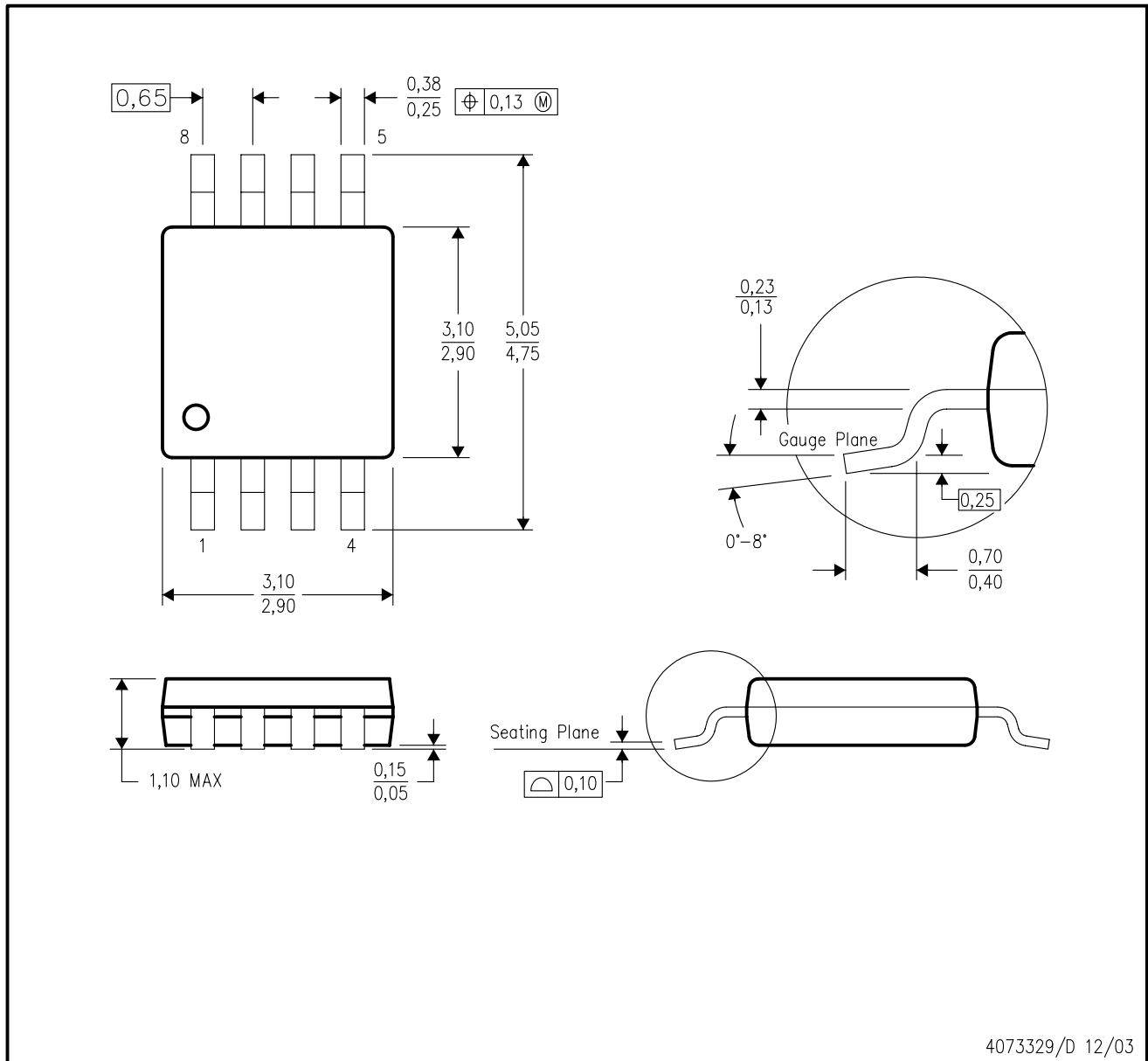
4073271/C 08/03

- NOTES:
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 - This drawing is subject to change without notice.
 - Body dimensions do not include mold flash or protrusion.
 - This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <<http://www.ti.com>>.
 - Falls within JEDEC MO-187

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DGK (S-PDSO-G8)

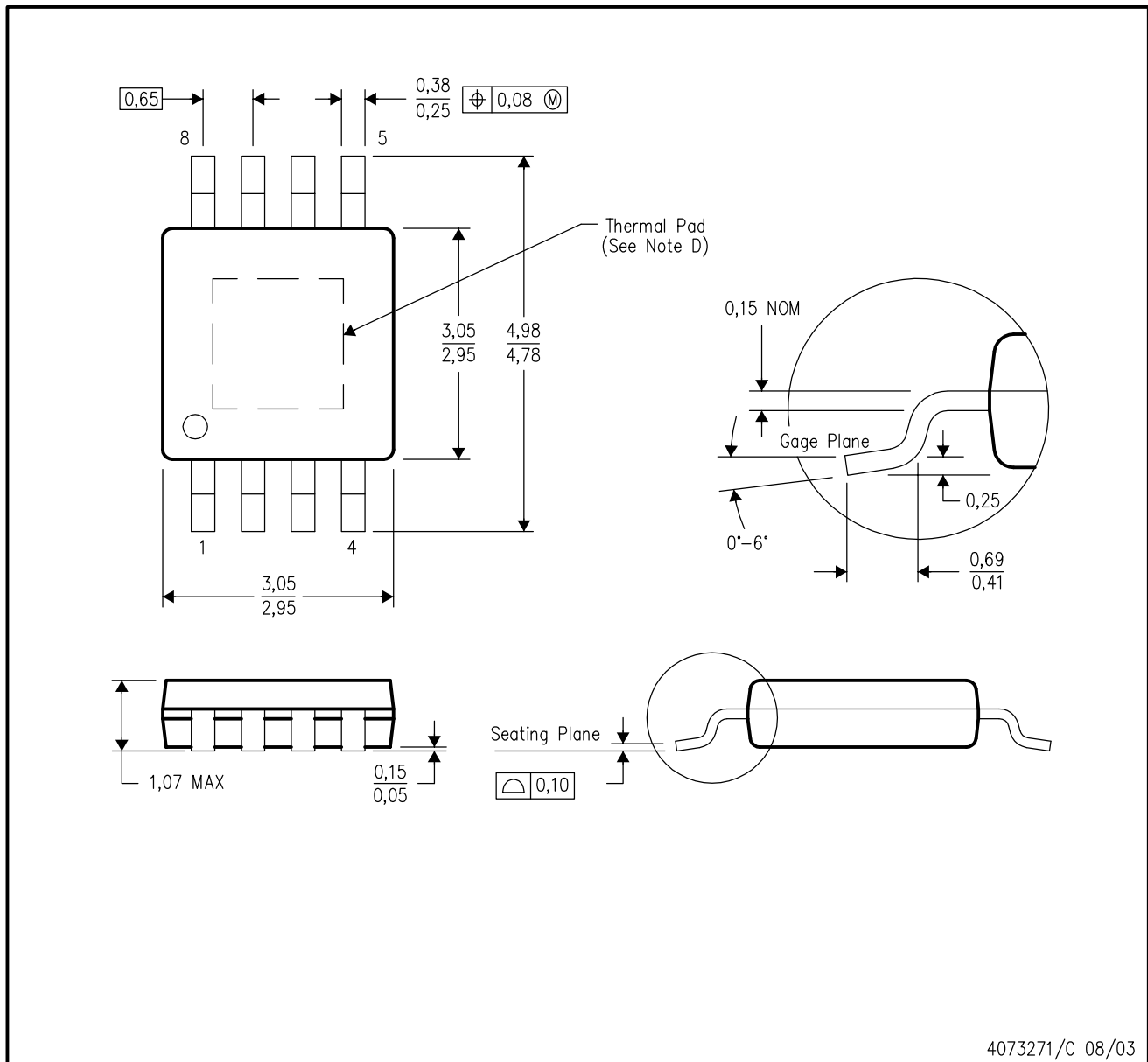
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DGN (S-PDSO-G8)

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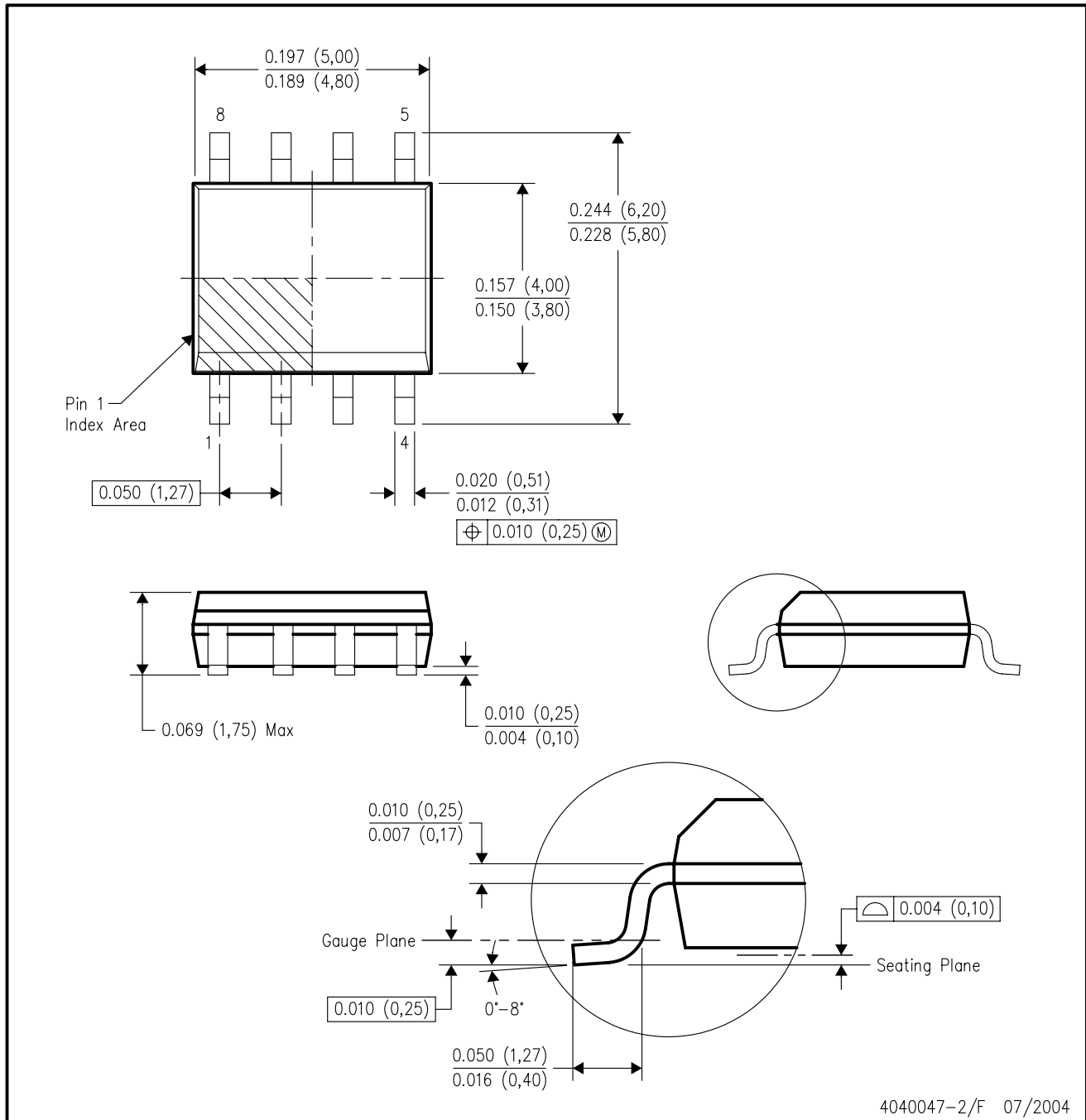
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- NOTES:
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 - This drawing is subject to change without notice.
 - Body dimensions do not include mold flash or protrusion.
 - This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <<http://www.ti.com>>.
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D (R-PDSO-G8)

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